CY966C0 Series

F^{2}MC-16FX 16-bit Microcontroller

CY966C0 series is based on Cypress's advanced F^{2}MC-16FX architecture (16-bit with instruction pipeline for RISC-like performance). The CPU uses the same instruction set as the established F^{2}MC-16LX family thus allowing for easy migration of F^{2}MC-16LX Software to the new F^{2}MC-16FX products. F^{2}MC-16FX product improvements compared to the previous generation include significantly improved performance - even at the same operation frequency, reduced power consumption and faster start-up time. For high processing speed at optimized power consumption an internal PLL can be selected to supply the CPU with up to 32MHz operation frequency from an external 4MHz to 8MHz resonator. The result is a minimum instruction cycle time of 31.2ns going together with excellent EMI behavior. The emitted power is minimized by the on-chip voltage regulator that reduces the internal CPU voltage. A flexible clock tree allows selecting suitable operation frequencies for peripheral resources independent of the CPU speed.

Features

Technology

0.18μm CMOS

CPU

■ F^{2}MC-16FX CPU

■ Optimized instruction set for controller applications (bit, byte, word and long-word data types, 23 different addressing modes, barrel shift, variety of pointers)

■ 8-byte instruction queue

■ Signed multiply (16-bit $\times$ 16-bit) and divide (32-bit/16-bit) instructions available

System Clock

■ On-chip PLL clock multiplier ($\times$1 to $\times$8, $\times$1 when PLL stop)

■ 4MHz to 8MHz crystal oscillator (maximum frequency when using ceramic resonator depends on Q-factor)

■ Up to 8MHz external clock for devices with fast clock input feature

■ 32.768kHz subsystem quartz clock

■ 100kHz/2MHz internal RC clock for quick and safe startup, clock stop detection function, watchdog

■ Clock source selectable from mainclock oscillator, subclock oscillator and on-chip RC oscillator, independently for CPU and 2 clock domains of peripherals

■ The subclock oscillator is enabled by the Boot ROM program controlled by a configuration marker after a Power or External reset

■ Low Power Consumption - 13 operating modes (different Run, Sleep, Timer, Stop modes)

On-Chip Voltage Regulator

Internal voltage regulator supports a wide MCU supply voltage range (Min=2.7V), offering low power consumption

Low Voltage Detection Function

Reset is generated when supply voltage falls below programmable reference voltage

Code Security

Protects Flash Memory content from unintended read-out

DMA

Automatic transfer function independent of CPU, can be assigned freely to resources

Interrupts

■ Fast Interrupt processing

■ 8 programmable priority levels

■ Non-Maskable Interrupt (NMI)

CAN

■ Supports CAN protocol version 2.0 part A and B

■ ISO16845 certified

■ Bit rates up to 1Mbps

■ 32 message objects

■ Each message object has its own identifier mask

■ Programmable FIFO mode (concatenation of message objects)

■ Maskable interrupt

■ Disabled Automatic Retransmission mode for Time Triggered CAN applications

■ Programmable loop-back mode for self-test operation

USART

■ Full duplex USARTs (SCI/LIN)

■ Wide range of baud rate settings using a dedicated reload timer

- Special synchronous options for adapting to different synchronous serial protocols

- LIN functionality working either as master or slave LIN device

- Extended support for LIN-Protocol to reduce interrupt load

I²C

- Up to 400kbps

- Master and Slave functionality, 7-bit and 10-bit addressing

A/D Converter

- SAR-type

- 8/10-bit resolution

- Signals interrupt on conversion end, single conversion mode, continuous conversion mode,
stop conversion mode, activation by software, external trigger, reload timers and PPGs

- Range Comparator Function

- Scan Disable Function

- ADC Pulse Detection Function

Source Clock Timers

Three independent clock timers (23-bit RC clock timer, 23-bit Main clock timer, 17-bit Sub clock timer)

Hardware Watchdog Timer

- Hardware watchdog timer is active after reset

- Window function of Watchdog Timer is used to select the lower window limit of the watchdog interval

Reload Timers

- 16-bit wide

- Prescaler with $1/2^1$, $1/2^2$, $1/2^3$, $1/2^4$, $1/2^5$, $1/2^6$ of peripheral clock frequency

- Event count function

Free-Running Timers

- Signals an interrupt on overflow, supports timer clear upon match with Output Compare (0, 4)

- Prescaler with 1, $1/2^1$, $1/2^2$, $1/2^3$, $1/2^4$, $1/2^5$, $1/2^6$, $1/2^7$, $1/2^8$ of peripheral clock frequency

Input Capture Units

- 16-bit wide

- Signals an interrupt upon external event

- Rising edge, Falling edge or Both (rising & falling) edges sensitive

Output Compare Units

- 16-bit wide

- Signals an interrupt when a match with Free-running Timer occurs

- A pair of compare registers can be used to generate an output signal

Programmable Pulse Generator

- 16-bit down counter, cycle and duty setting registers

- Can be used as $2 \times$ 8-bit PPG

- Interrupt at trigger, counter borrow and/or duty match

- PWM operation and one-shot operation

- Internal prescaler allows 1, 1/4, 1/16, 1/64 of peripheral clock as counter clock or of selected Reload timer underflow as clock input

- Can be triggered by software or reload timer

- Can trigger ADC conversion

- Timing point capture

- Start delay

Quadrature Position/Revolution Counter (QPRC)

- Up/down count mode, Phase difference count mode, Count mode with direction

- 16-bit position counter

- 16-bit revolution counter

- Two 16-bit compare registers with interrupt

- Detection edge of the three external event input pins AIN, BIN and ZIN is configurable

LCD Controller

- LCD controller with up to 4COM $\times$ 44SEG

- Internal or external voltage generation

- Duty cycle: Selectable from options: 1/2, 1/3 and 1/4

- Fixed 1/3 bias

- Programmable frame period

- Clock source selectable from four options (main clock, peripheral clock, subclock or RC oscillator clock)

- Internal divider resistors or external divider resistors

- On-chip data memory for display

- LCD display can be operated in Timer Mode

- Blank display: selectable

- All SEG, COM and V pins can be switched between general and specialized purposes

Sound Generator

- 8-bit PWM signal is mixed with tone frequency from 16-bit reload counter

■ PWM clock by internal prescaler: 1, 1/2, 1/4, 1/8 of peripheral clock

Real Time Clock

■ Operational on main oscillation (4MHz), sub oscillation (32kHz) or RC oscillation (100kHz/2MHz)

■ Capable to correct oscillation deviation of Sub clock or RC oscillator clock (clock calibration)

■ Read/write accessible second/minute/hour registers

■ Can signal interrupts every half second/second/minute/hour/day

■ Internal clock divider and prescaler provide exact 1s clock

External Interrupts

■ Edge or Level sensitive

■ Interrupt mask bit per channel

■ Each available CAN channel RX has an external interrupt for wake-up

■ Selected USART channels SIN have an external interrupt for wake-up

Non Maskable Interrupt

■ Disabled after reset, can be enabled by Boot-ROM depending on ROM configuration block

■ Once enabled, cannot be disabled other than by reset

■ High or Low level sensitive

■ Pin shared with external interrupt 0

I/O Ports

■ Most of the external pins can be used as general purpose I/O

■ All push-pull outputs (except when used as I²C SDA/SCL line)

■ Bit-wise programmable as input/output or peripheral signal

■ Bit-wise programmable input enable

■ One input level per GPIO-pin (either Automotive or CMOS hysteresis)

■ Bit-wise programmable pull-up resistor

■ Some pins offer high current output capability for LED driving.

Built-in On Chip Debugger (OCD)

■ One-wire debug tool interface

■ Break function:
  □ Hardware break: 6 points (shared with code event)
  □ -Software break: 4096 points

■ Event function
  □ Code event: 6 points (shared with hardware break)
  □ -Data event: 6 points
  □ Event sequencer: 2 levels + reset

■ Execution time measurement function

■ Trace function: 42 branches

■ Security function

Flash Memory

■ Dual operation flash allowing reading of one Flash bank while programming or erasing the other bank

■ Command sequencer for automatic execution of programming algorithm and for supporting DMA for programming of the Flash Memory

■ Supports automatic programming, Embedded Algorithm

■ Write/Erase/Erase-Suspend/Resume commands

■ A flag indicating completion of the automatic algorithm

■ Erase can be performed on each sector individually

■ Sector protection

■ Flash Security feature to protect the content of the Flash

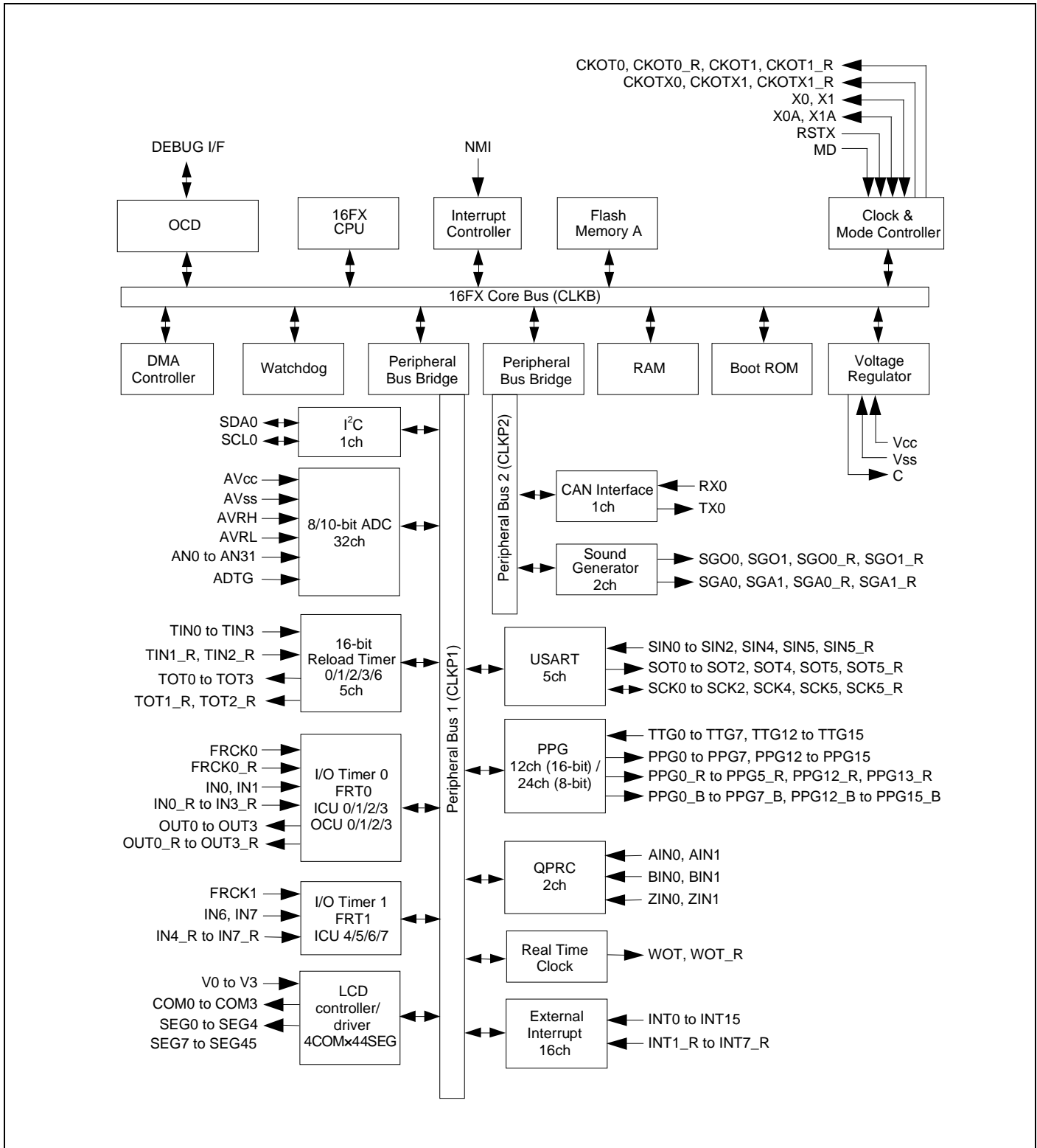■ Low voltage detection during Flash erase or write

Contents

Product Lineup

Features		CY966C0	Remark
Product Type		Flash Memory Product	
Subclock		Subclock can be set by software	
Dual Operation Flash Memory	RAM	-	
128.5KB + 32KB	8KB	CY96F6C5R, CY96F6C5A	Product Options R: MCU with CAN
256.5KB + 32KB	16KB	CY96F6C6R	A: MCU without CAN
Package		LQFP-120 LQM120	
DMA		4ch	
USART		5ch	LIN-USART 0 to 2/4/5
	with automatic LIN-Header transmission/reception	2ch	LIN-USART 0/1
	with 16 byte RX- and TX-FIFO		
I²C		1ch	I²C 0
8/10-bit A/D Converter		32ch	AN 0 to 31
	with Data Buffer	No	
	with Range Comparator	Yes	
	with Scan Disable	Yes	
	with ADC Pulse Detection	Yes	
16-bit Reload Timer (RLT)		5ch	RLT 0 to 3/6
16-bit Free-Running Timer (FRT)		2ch	FRT 0/1
16-bit Input Capture Unit (ICU)		8ch (5 channels for LIN-USART)	ICU 0 to 7 (ICU 0/1/4 to 6 for LIN-USART)
16-bit Output Compare Unit (OCU)		4ch	OCU 0 to 3
8/16-bit Programmable Pulse Generator (PPG)		12ch (16-bit) / 24ch (8-bit)	PPG 0 to 7/12 to 15
	with Timing point capture	Yes	
	with Start delay	Yes	
	with Ramp	No	
Quadrature Position/Revolution Counter (QPRC)		2ch	QPRC 0/1
CAN Interface		1ch	CAN 0 32 Message Buffers
External Interrupts (INT)		16ch	INT 0 to 15
Non-Maskable Interrupt (NMI)		1ch	
Sound Generator (SG)		2ch	SG 0/1
LCD Controller		4COM × 44SEG	COM 0 to 3 SEG 0 to 4/7 to 45
Real Time Clock (RTC)		1ch	
I/O Ports		97 (Dual clock mode) 99 (Single clock mode)	
Clock Calibration Unit (CAL)		1ch	
Clock Output Function		2ch	
Low Voltage Detection Function		Yes	Low voltage detection function can be disabled by software
Hardware Watchdog Timer		Yes	
On-chip RC-oscillator		Yes	
On-chip Debugger		Yes	

Note: All signals of the peripheral function in each product cannot be allocated by limiting the pins of package.
It is necessary to use the port relocate function of the general I/O port according to your function use.

1. Block Diagram

2. Pin Assignment

(Top view)

LQFP - 120

(LQM120)

*1: CMOS input level only

*2: CMOS input level only for I²C

*3: Please set ROM Configuration Block (RCB) to use the subclock.

Other than those above, general-purpose pins have only Automotive input level.

Left side pins (top to bottom):

Pin	Signal
91	Vss
92	P00_3 / SEG15 / INT6_R
93	P00_4 / SEG16 / INT7_R
94	P00_5 / SEG17 / IN6 / TTG2 / TTG6
95	P00_6 / SEG18 / IN7 / TTG3 / TTG7
96	P00_7 / SEG19 / SGO0 / INT14
97	P01_0 / SEG20 / SGA0
98	P01_1 / SEG21 / CKOT1 / OUT0
99	P01_2 / SEG22 / CKOTX1 / OUT1 / INT15
100	P01_3 / SEG23 / PPG5
101	P01_4 / SEG24 / SIN4 / INT8*1
102	P01_5 / SEG25 / SOT4
103	P01_6 / SEG26 / SCK4 / TTG12*1
104	P01_7 / SEG27 / CKOTX1_R / INT9 / TTG13 / ZIN0
105	P02_0 / SEG28 / CKOT1_R / INT10 / TTG14 / AIN0
106	P02_1 / SEG29 / IN6_R / TTG15
107	P02_2 / SEG30 / IN7_R / CKOT0_R / INT12 / BIN0
108	P02_3 / SEG31 / SGO0_R / PPG12_B
109	P02_4 / SEG32 / SGA0_R / PPG13_B
110	P02_5 / SEG33 / OUT0_R / INT13 / SIN5_R*1
111	P02_6 / SEG34 / OUT1_R
112	P02_7 / SEG35 / PPG5_R
113	P03_0 / V0 / SEG36 / PPG4_B
114	P03_1 / V1 / SEG37 / PPG5_B
115	P03_2 / V2 / SEG38 / PPG14_B / SOT5_R
116	P03_3 / V3 / SEG39 / PPG15_B / SCK5_R*1
117	P03_4 / RX0 / INT4*1
118	P03_5 / TX0
119	P03_6 / INT0 / NMI
120	Vcc

Right side pins (top to bottom):

Pin	Signal
60	Vcc
59	P10_3 / PPG7 / AN31
58	P10_2 / SCK2 / PPG6 / AN30*1
57	P10_1 / SOT2 / TOT3 / AN29
56	P10_0 / SIN2 / TIN3 / INT11 / AN28*1
55	P09_7 / PPG15
54	Vss
53	Vcc
52	P09_6 / PPG14
51	P09_5 / PPG13
50	P09_4 / PPG12
49	P09_3 / AN27
48	P09_2 / AN26
47	P09_1 / AN25
46	P09_0 / AN24
45	P08_7 / AN23 / PPG7_B
44	P08_6 / AN22 / PPG6_B
43	P08_5 / AN21
42	P17_2 / PPG13_R
41	P17_1 / PPG12_R
40	P08_4 / AN20
39	P08_3 / AN19
38	P08_2 / AN18
37	P08_1 / AN17
36	P08_0 / AN16
35	P05_7 / AN15 / TOT2 / SGA1_R
34	P05_6 / AN14 / TIN2 / SGO1_R
33	P05_5 / AN13
32	P05_4 / AN12 / INT2_R / WOT_R
31	Vss

Top side pins (90 to 61):

Pin	Signal
90	Vcc
89	P00_2 / SEG14 / INT5_R
88	P00_1 / SEG13 / INT4_R
87	P00_0 / SEG12 / INT3_R
86	P12_7 / SEG11 / INT1_R
85	P12_6 / SEG10 / TOT2_R / PPG3_B
84	P12_5 / SEG9 / TIN2_R / PPG2_B
83	P12_4 / SEG8 / OUT3_R
82	P12_3 / SEG7 / OUT2_R
81	P12_2 / TOT1_R / PPG1_B
80	P12_1 / TIN1_R / PPG0_B
79	P12_0 / SEG4 / IN1_R / BIN1
78	P11_7 / SEG3 / IN0_R / AIN1
77	P11_6 / SEG2 / FRCK0_R / ZIN1
76	P11_5 / SEG1 / PPG4_R
75	P11_4 / SEG0 / PPG3_R
74	P11_3 / COM3 / PPG2_R
73	P11_2 / COM2 / PPG1_R
72	P11_1 / COM1 / PPG0_R
71	P11_0 / COM0
70	RSTX
69	P04_1 / X1A*3
68	P04_0 / X0A*3
67	Vss
66	X1
65	X0
64	MD
63	P17_0
62	DEBUG I/F
61	Vss

Bottom side pins (1 to 30):

Pin	Signal
1	Vss
2	C
3	P03_7 / INT1 / SIN1 / SEG40*1
4	P13_0 / INT2 / SOT1 / SEG41
5	P13_1 / INT3 / SCK1 / SEG42*1
6	P13_2 / PPG0 / TIN0 / FRCK1 / SEG43
7	P13_3 / PPG1 / TOT0 / WOT / SEG44
8	P13_4 / SIN0 / INT6 / SEG45*1
9	P13_5 / SOT0 / ADTG / INT7
10	P13_6 / SCK0 / CKOTX0*1
11	P13_7 / PPG2 / CKOT0
12	P04_4 / PPG3 / SDA0*2
13	P04_5 / PPG4 / SCL0*2
14	P06_0 / AN0 / IN2_R / SCK5*1
15	P06_1 / AN1 / IN3_R / SOT5
16	P06_2 / AN2 / INT5 / SIN5*1
17	P06_3 / AN3 / FRCK0
18	P06_4 / AN4 / IN0 / TTG0 / TTG4
19	P06_5 / AN5 / IN1 / TTG1 / TTG5
20	P06_6 / AN6 / TIN1 / IN4_R
21	P06_7 / AN7 / TOT1 / IN5_R
22	AVcc
23	AVRH
24	AVRL
25	AVss
26	P05_0 / AN8
27	P05_1 / AN9
28	P05_2 / AN10 / OUT2 / SGO1
29	P05_3 / AN11 / OUT3 / SGA1
30	Vcc

3. Pin Description

Pin Name	Feature	Description
ADTG	ADC	A/D converter trigger input pin
AINn	QPRC	Quadrature Position/Revolution Counter Unit n input pin
ANn	ADC	A/D converter channel n input pin
AVcc	Supply	Analog circuits power supply pin
AVRH	ADC	A/D converter high reference voltage input pin
AVRL	ADC	A/D converter low reference voltage input pin
AVss	Supply	Analog circuits power supply pin
BINn	QPRC	Quadrature Position/Revolution Counter Unit n input pin
C	Voltage regulator	Internally regulated power supply stabilization capacitor pin
CKOTn	Clock Output function	Clock Output function n output pin
CKOTn_R	Clock Output function	Relocated Clock Output function n output pin
CKOTXn	Clock Output function	Clock Output function n inverted output pin
CKOTXn_R	Clock Output function	Relocated Clock Output function n inverted output pin
COMn	LCD	LCD Common driver pin
DEBUG I/F	OCD	On Chip Debugger input/output pin
FRCKn	Free-Running Timer	Free-Running Timer n input pin
FRCKn_R	Free-Running Timer	Relocated Free-Running Timer n input pin
INn	ICU	Input Capture Unit n input pin
INn_R	ICU	Relocated Input Capture Unit n input pin
INTn	External Interrupt	External Interrupt n input pin
INTn_R	External Interrupt	Relocated External Interrupt n input pin
MD	Core	Input pin for specifying the operating mode
NMI	External Interrupt	Non-Maskable Interrupt input pin
OUTn	OCU	Output Compare Unit n waveform output pin
OUTn_R	OCU	Relocated Output Compare Unit n waveform output pin
Pnn_m	GPIO	General purpose I/O pin
PPGn	PPG	Programmable Pulse Generator n output pin (16bit/8bit)
PPGn_R	PPG	Relocated Programmable Pulse Generator n output pin (16bit/8bit)
PPGn_B	PPG	Programmable Pulse Generator n output pin (16bit/8bit)
RSTX	Core	Reset input pin
RXn	CAN	CAN interface n RX input pin
SCKn	USART	USART n serial clock input/output pin
SCKn_R	USART	Relocated USART n serial clock input/output pin
SCLn	I^2C	I^2C interface n clock I/O input/output pin
SDAn	I^2C	I^2C interface n serial data I/O input/output pin
SEGn	LCD	LCD Segment driver pin
SGAn	Sound Generator	Sound Generator amplitude output pin
SGAn_R	Sound Generator	Relocated Sound Generator amplitude output pin
SGOn	Sound Generator	Sound Generator sound/tone output pin
SGOn_R	Sound Generator	Relocated Sound Generator sound/tone output pin

Pin Name	Feature	Description
SINn	USART	USART n serial data input pin
SINn_R	USART	Relocated USART n serial data input pin
SOTn	USART	USART n serial data output pin
SOTn_R	USART	Relocated USART n serial data output pin
TINn	Reload Timer	Reload Timer n event input pin
TINn_R	Reload Timer	Relocated Reload Timer n event input pin
TOTn	Reload Timer	Reload Timer n output pin
TOTn_R	Reload Timer	Relocated Reload Timer n output pin
TTGn	PPG	Programmable Pulse Generator n trigger input pin
TXn	CAN	CAN interface n TX output pin
Vn	LCD	LCD voltage reference pin
Vcc	Supply	Power supply pin
Vss	Supply	Power supply pin
WOT	RTC	Real Time clock output pin
WOT_R	RTC	Relocated Real Time clock output pin
X0	Clock	Oscillator input pin
X0A	Clock	Subclock Oscillator input pin
X1	Clock	Oscillator output pin
X1A	Clock	Subclock Oscillator output pin
ZINn	QPRC	Quadrature Position/Revolution Counter Unit n input pin

4. Pin Circuit Type

Pin No.	I/O Circuit Type*	Pin Name
1	Supply	Vss
2	F	C
3	P	P03_7 / INT1 / SIN1 / SEG40
4	J	P13_0 / INT2 / SOT1 / SEG41
5	P	P13_1 / INT3 / SCK1 / SEG42
6	J	P13_2 / PPG0 / TIN0 / FRCK1 / SEG43
7	J	P13_3 / PPG1 / TOT0 / WOT / SEG44
8	P	P13_4 / SIN0 / INT6 / SEG45
9	H	P13_5 / SOT0 / ADTG / INT7
10	M	P13_6 / SCK0 / CKOTX0
11	H	P13_7 / PPG2 / CKOT0
12	N	P04_4 / PPG3 / SDA0
13	N	P04_5 / PPG4 / SCL0
14	I	P06_0 / AN0 / IN2_R / SCK5
15	K	P06_1 / AN1 / IN3_R / SOT5
16	I	P06_2 / AN2 / INT5 / SIN5
17	K	P06_3 / AN3 / FRCK0
18	K	P06_4 / AN4 / IN0 / TTG0 / TTG4
19	K	P06_5 / AN5 / IN1 / TTG1 / TTG5
20	K	P06_6 / AN6 / TIN1 / IN4_R
21	K	P06_7 / AN7 / TOT1 / IN5_R
22	Supply	AVcc
23	G	AVRH
24	G	AVRL
25	Supply	AVss
26	K	P05_0 / AN8
27	K	P05_1 / AN9
28	K	P05_2 / AN10 / OUT2 / SGO1
29	K	P05_3 / AN11 / OUT3 / SGA1
30	Supply	Vcc
31	Supply	Vss
32	K	P05_4 / AN12 / INT2_R / WOT_R
33	K	P05_5 / AN13
34	K	P05_6 / AN14 / TIN2 / SGO1_R
35	K	P05_7 / AN15 / TOT2 / SGA1_R
36	V	P08_0 / AN16
37	V	P08_1 / AN17
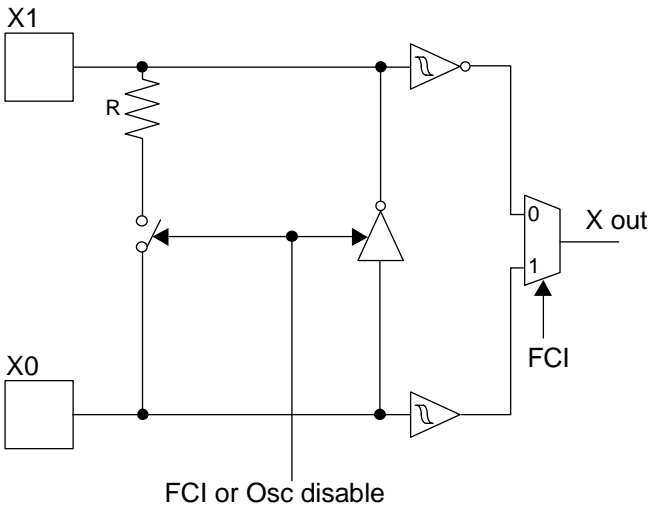
Pin No.	I/O Circuit Type*	Pin Name
38	V	P08_2 / AN18
39	V	P08_3 / AN19
40	V	P08_4 / AN20
41	H	P17_1 / PPG12_R
42	H	P17_2 / PPG13_R
43	V	P08_5 / AN21
44	V	P08_6 / AN22 / PPG6_B
45	V	P08_7 / AN23 / PPG7_B
46	V	P09_0 / AN24
47	V	P09_1 / AN25
48	V	P09_2 / AN26
49	V	P09_3 / AN27
50	Y	P09_4 / PPG12
51	Y	P09_5 / PPG13
52	Y	P09_6 / PPG14
53	Supply	Vcc
54	Supply	Vss
55	Y	P09_7 / PPG15
56	W	P10_0 / SIN2 / TIN3 / INT11 / AN28
57	V	P10_1 / SOT2 / TOT3 / AN29
58	W	P10_2 / SCK2 / PPG6 / AN30
59	V	P10_3 / PPG7 / AN31
60	Supply	Vcc
61	Supply	Vss
62	O	DEBUG I/F
63	H	P17_0
64	C	MD
65	A	X0
66	A	X1
67	Supply	Vss
68	B	P04_0 / X0A
69	B	P04_1 / X1A
70	C	RSTX
71	J	P11_0 / COM0
72	J	P11_1 / COM1 / PPG0_R
73	J	P11_2 / COM2 / PPG1_R
74	J	P11_3 / COM3 / PPG2_R
75	J	P11_4 / SEG0 / PPG3_R
76	J	P11_5 / SEG1 / PPG4_R

Pin No.	I/O Circuit Type*	Pin Name
77	J	P11_6 / SEG2 / FRCK0_R / ZIN1
78	J	P11_7 / SEG3 / IN0_R / AIN1
79	J	P12_0 / SEG4 / IN1_R / BIN1
80	H	P12_1 / TIN1_R / PPG0_B
81	H	P12_2 / TOT1_R / PPG1_B
82	J	P12_3 / SEG7 / OUT2_R
83	J	P12_4 / SEG8 / OUT3_R
84	J	P12_5 / SEG9 / TIN2_R / PPG2_B
85	J	P12_6 / SEG10 / TOT2_R / PPG3_B
86	J	P12_7 / SEG11 / INT1_R
87	J	P00_0 / SEG12 / INT3_R
88	J	P00_1 / SEG13 / INT4_R
89	J	P00_2 / SEG14 / INT5_R
90	Supply	Vcc
91	Supply	Vss
92	J	P00_3 / SEG15 / INT6_R
93	J	P00_4 / SEG16 / INT7_R
94	J	P00_5 / SEG17 / IN6 / TTG2 / TTG6
95	J	P00_6 / SEG18 / IN7 / TTG3 / TTG7
96	J	P00_7 / SEG19 / SGO0 / INT14
97	J	P01_0 / SEG20 / SGA0
98	J	P01_1 / SEG21 / CKOT1 / OUT0
99	J	P01_2 / SEG22 / CKOTX1 / OUT1 / INT15
100	J	P01_3 / SEG23 / PPG5
101	P	P01_4 / SEG24 / SIN4 / INT8
102	J	P01_5 / SEG25 / SOT4
103	P	P01_6 / SEG26 / SCK4 / TTG12
104	J	P01_7 / SEG27 / CKOTX1_R / INT9 / TTG13 / ZIN0
105	J	P02_0 / SEG28 / CKOT1_R / INT10 / TTG14 / AIN0
106	J	P02_1 / SEG29 / IN6_R / TTG15
107	J	P02_2 / SEG30 / IN7_R / CKOT0_R / INT12 / BIN0
108	J	P02_3 / SEG31 / SGO0_R / PPG12_B
109	J	P02_4 / SEG32 / SGA0_R / PPG13_B
110	P	P02_5 / SEG33 / OUT0_R / INT13 / SIN5_R
111	J	P02_6 / SEG34 / OUT1_R
112	J	P02_7 / SEG35 / PPG5_R
113	L	P03_0 / V0 / SEG36 / PPG4_B
114	L	P03_1 / V1 / SEG37 / PPG5_B
115	L	P03_2 / V2 / SEG38 / PPG14_B / SOT5_R

Pin No.	I/O Circuit Type*	Pin Name
116	Q	P03_3 / V3 / SEG39 / PPG15_B / SCK5_R
117	M	P03_4 / RX0 / INT4
118	H	P03_5 / TX0
119	H	P03_6 / INT0 / NMI
120	Supply	Vcc

*: See "I/O Circuit Type" for details on the I/O circuit types.

5. I/O Circuit Type

Type	Circuit	Remarks
A		High-speed oscillation circuit: ■ Programmable between oscillation mode (external crystal or resonator connected to X0/X1 pins) and Fast external Clock Input (FCI) mode (external clock connected to X0 pin) ■ Feedback resistor = approx. 1.0MΩ ■ The amplitude: 1.8V±0.15V to operate by the internal supply voltage

Type	Circuit	Remarks
B		Low-speed oscillation circuit shared with GPIO functionality: ■Feedback resistor = approx. 5.0MΩ ■GPIO functionality selectable (CMOS level output (I_{OL} = 4mA, I_{OH} = -4mA), Automotive input with input shutdown function and programmable pull-up resistor)
C		CMOS hysteresis input pin

Type	Circuit	Remarks
F		Power supply input protection circuit
G		■A/D converter ref+ (AVRH)/ ref- (AVRL) power supply input pin with protection circuit ■Without protection circuit against V_{CC} for pins AVRH/AVRL
H		■CMOS level output (I_{OL} = 4mA, I_{OH} = -4mA) ■Automotive input with input shutdown function ■Programmable pull-up resistor
I		■CMOS level output (I_{OL} = 4mA, I_{OH} = -4mA) ■CMOS hysteresis input with input shutdown function ■Programmable pull-up resistor ■Analog input

Type	Circuit	Remarks
J		■ CMOS level output (I_{OL} = 4mA, I_{OH} = -4mA) ■ Automotive input with input shutdown function ■ Programmable pull-up resistor ■ SEG or COM output
K		■ CMOS level output (I_{OL} = 4mA, I_{OH} = -4mA) ■ Automotive input with input shutdown function ■ Programmable pull-up resistor ■ Analog input
L		■ CMOS level output (I_{OL} = 4mA, I_{OH} = -4mA) ■ Automotive input with input shutdown function ■ Programmable pull-up resistor ■ Vn input or SEG output

Type	Circuit	Remarks
M		■CMOS level output (I_{OL} = 4mA, I_{OH} = -4mA) ■CMOS hysteresis input with input shutdown function ■Programmable pull-up resistor
N		■CMOS level output (I_{OL} = 3mA, I_{OH} = -3mA) ■CMOS hysteresis input with input shutdown function ■Programmable pull-up resistor *: N-channel transistor has slew rate control according to I^{2}C spec, irrespective of usage.
O		■Open-drain I/O ■Output 25mA, Vcc = 2.7V ■TTL input

Type	Circuit	Remarks
P		■ CMOS level output (I_{OL} = 4mA, I_{OH} = -4mA) ■ CMOS hysteresis inputs with input shutdown function ■ Programmable pull-up resistor ■ SEG or COM output
Q		■ CMOS level output (I_{OL} = 4mA, I_{OH} = -4mA) ■ CMOS hysteresis inputs with input shutdown function ■ Programmable pull-up resistor ■ Vn input or SEG output
V		■ CMOS level output (programmable I_{OL} = 4mA, I_{OH} = -4mA and I_{OL} = 20mA, I_{OH} = -20mA) ■ Automotive input with input shutdown function ■ Programmable pull-up resistor ■ Analog input

Type	Circuit	Remarks
W		■CMOS level output (programmable I_{OL} = 4mA, I_{OH} = -4mA and I_{OL} = 20mA, I_{OH} = -20mA) ■CMOS hysteresis input with input shutdown function ■Programmable pull-up resistor ■Analog input
Y		■CMOS level output (programmable I_{OL} = 4mA, I_{OH} = -4mA and I_{OL} = 20mA, I_{OH} = -20mA) ■Automotive input with input shutdown function ■Programmable pull-up resistor

6. Memory Map

Address	Region
FF:FFFF$_H$	USER ROM*1
DE:0000$_H$	
DD:FFFF$_H$	Reserved
10:0000$_H$	
0F:C000$_H$	Boot-ROM
0E:9000$_H$	Peripheral
	Reserved
01:0000$_H$	
00:8000$_H$	ROM/RAM MIRROR
RAMSTART0*2	Internal RAM bank0
	Reserved
00:0C00$_H$	
00:0380$_H$	Peripheral
00:0180$_H$	GPR*3
00:0100$_H$	DMA
00:00F0$_H$	Reserved
00:0000$_H$	Peripheral

*1: For details about USER ROM area, see "User ROM Memory Map for Flash Devices" on the following pages.
*2: For RAMSTART addresses, see the table on the next page.
*3: Unused GPR banks can be used as RAM area.
  GPR: General-Purpose Register
The DMA area is only available if the device contains the corresponding resource.
The available RAM and ROM area depends on the device.

7. RAMSTART Addresses

Devices	Bank 0 RAM Size	RAMSTART0
CY96F6C5	8KB	$00:6200_H$
CY96F6C6	16KB	$00:4200_H$

8. User ROM Memory Map for Flash Devices

CPU mode address	Flash memory mode address	CY96F6C5 Flash size 128.5KB + 32KB	CY96F6C6 Flash size 256.5KB + 32KB	
FF:FFFF$_H$ FF:0000$_H$	3F:FFFF$_H$ 3F:0000$_H$	SA39 - 64KB	SA39 - 64KB	Bank A of Flash A
FE:FFFF$_H$ FE:0000$_H$	3E:FFFF$_H$ 3E:0000$_H$	SA38 - 64KB	SA38 - 64KB	Bank A of Flash A
FD:FFFF$_H$ FD:0000$_H$	3D:FFFF$_H$ 3D:0000$_H$	Reserved	SA37 - 64KB	Bank A of Flash A
FC:FFFF$_H$ FC:0000$_H$	3C:FFFF$_H$ 3C:0000$_H$	Reserved	SA36 - 64KB	Bank A of Flash A
FB:FFFF$_H$ ... DF:A000		Reserved	Reserved	
DF:9FFF$_H$ DF:8000$_H$	1F:9FFF$_H$ 1F:8000$_H$	SA4 - 8KB	SA4 - 8KB	Bank B of Flash A
DF:7FFF$_H$ DF:6000$_H$	1F:7FFF$_H$ 1F:6000$_H$	SA3 - 8KB	SA3 - 8KB	Bank B of Flash A
DF:5FFF$_H$ DF:4000$_H$	1F:5FFF$_H$ 1F:4000$_H$	SA2 - 8KB	SA2 - 8KB	Bank B of Flash A
DF:3FFF$_H$ DF:2000$_H$	1F:3FFF$_H$ 1F:2000$_H$	SA1 - 8KB	SA1 - 8KB	Bank B of Flash A
DF:1FFF$_H$ DF:0000$_H$	1F:1FFF$_H$ 1F:0000$_H$	SAS - 512B*	SAS - 512B*	Bank A of Flash A
DE:FFFF$_H$ DE:0000$_H$		Reserved	Reserved	

*: Physical address area of SAS-512B is from DF:0000$_H$ to DF:01FF$_H$.

Others (from DF:0200$_H$ to DF:1FFF$_H$) is mirror area of SAS-512B.

Sector SAS contains the ROM configuration block RCBA at CPU address DF:0000$_H$ -DF:01FF$_H$.

SAS cannot be used for E^{2}PROM emulation.

9. Serial Programming Communication Interface

USART pins for Flash serial programming (MD = 0, DEBUG I/F = 0, Serial Communication mode)

CY966C0		
Pin Number	**USART Number**	**Normal Function**
8	USART0	SIN0
9		SOT0
10		SCK0
3	USART1	SIN1
4		SOT1
5		SCK1
56	USART2	SIN2
57		SOT2
58		SCK2
101	USART4	SIN4
102		SOT4
103		SCK4

10. Interrupt Vector Table

Vector Number	Offset in Vector Table	Vector Name	Cleared by DMA	Index in ICR to Program	Description
0	3FC$_H$	CALLV0	No	-	CALLV instruction
1	3F8$_H$	CALLV1	No	-	CALLV instruction
2	3F4$_H$	CALLV2	No	-	CALLV instruction
3	3F0$_H$	CALLV3	No	-	CALLV instruction
4	3EC$_H$	CALLV4	No	-	CALLV instruction
5	3E8$_H$	CALLV5	No	-	CALLV instruction
6	3E4$_H$	CALLV6	No	-	CALLV instruction
7	3E0$_H$	CALLV7	No	-	CALLV instruction
8	3DC$_H$	RESET	No	-	Reset vector
9	3D8$_H$	INT9	No	-	INT9 instruction
10	3D4$_H$	EXCEPTION	No	-	Undefined instruction execution
11	3D0$_H$	NMI	No	-	Non-Maskable Interrupt
12	3CC$_H$	DLY	No	12	Delayed Interrupt
13	3C8$_H$	RC_TIMER	No	13	RC Clock Timer
14	3C4$_H$	MC_TIMER	No	14	Main Clock Timer
15	3C0$_H$	SC_TIMER	No	15	Sub Clock Timer
16	3BC$_H$	LVDI	No	16	Low Voltage Detector
17	3B8$_H$	EXTINT0	Yes	17	External Interrupt 0
18	3B4$_H$	EXTINT1	Yes	18	External Interrupt 1
19	3B0$_H$	EXTINT2	Yes	19	External Interrupt 2
20	3AC$_H$	EXTINT3	Yes	20	External Interrupt 3
21	3A8$_H$	EXTINT4	Yes	21	External Interrupt 4
22	3A4$_H$	EXTINT5	Yes	22	External Interrupt 5
23	3A0$_H$	EXTINT6	Yes	23	External Interrupt 6
24	39C$_H$	EXTINT7	Yes	24	External Interrupt 7
25	398$_H$	EXTINT8	Yes	25	External Interrupt 8
26	394$_H$	EXTINT9	Yes	26	External Interrupt 9
27	390$_H$	EXTINT10	Yes	27	External Interrupt 10
28	38C$_H$	EXTINT11	Yes	28	External Interrupt 11
29	388$_H$	EXTINT12	Yes	29	External Interrupt 12
30	384$_H$	EXTINT13	Yes	30	External Interrupt 13
31	380$_H$	EXTINT14	Yes	31	External Interrupt 14
32	37C$_H$	EXTINT15	Yes	32	External Interrupt 15
33	378$_H$	CAN0	No	33	CAN Controller 0
34	374$_H$	-	-	34	Reserved
35	370$_H$	-	-	35	Reserved
36	36C$_H$	-	-	36	Reserved
37	368$_H$	-	-	37	Reserved
38	364$_H$	PPG0	Yes	38	Programmable Pulse Generator 0
39	360$_H$	PPG1	Yes	39	Programmable Pulse Generator 1

Vector Number	Offset in Vector Table	Vector Name	Cleared by DMA	Index in ICR to Program	Description
40	35C$_H$	PPG2	Yes	40	Programmable Pulse Generator 2
41	358$_H$	PPG3	Yes	41	Programmable Pulse Generator 3
42	354$_H$	PPG4	Yes	42	Programmable Pulse Generator 4
43	350$_H$	PPG5	Yes	43	Programmable Pulse Generator 5
44	34C$_H$	PPG6	Yes	44	Programmable Pulse Generator 6
45	348$_H$	PPG7	Yes	45	Programmable Pulse Generator 7
46	344$_H$	-	-	46	Reserved
47	340$_H$	-	-	47	Reserved
48	33C$_H$	-	-	48	Reserved
49	338$_H$	-	-	49	Reserved
50	334$_H$	PPG12	Yes	50	Programmable Pulse Generator 12
51	330$_H$	PPG13	Yes	51	Programmable Pulse Generator 13
52	32C$_H$	PPG14	Yes	52	Programmable Pulse Generator 14
53	328$_H$	PPG15	Yes	53	Programmable Pulse Generator 15
54	324$_H$	-	-	54	Reserved
55	320$_H$	-	-	55	Reserved
56	31C$_H$	-	-	56	Reserved
57	318$_H$	-	-	57	Reserved
58	314$_H$	RLT0	Yes	58	Reload Timer 0
59	310$_H$	RLT1	Yes	59	Reload Timer 1
60	30C$_H$	RLT2	Yes	60	Reload Timer 2
61	308$_H$	RLT3	Yes	61	Reload Timer 3
62	304$_H$	-	-	62	Reserved
63	300$_H$	-	-	63	Reserved
64	2FC$_H$	RLT6	Yes	64	Reload Timer 6
65	2F8$_H$	ICU0	Yes	65	Input Capture Unit 0
66	2F4$_H$	ICU1	Yes	66	Input Capture Unit 1
67	2F0$_H$	ICU2	Yes	67	Input Capture Unit 2
68	2EC$_H$	ICU3	Yes	68	Input Capture Unit 3
69	2E8$_H$	ICU4	Yes	69	Input Capture Unit 4
70	2E4$_H$	ICU5	Yes	70	Input Capture Unit 5
71	2E0$_H$	ICU6	Yes	71	Input Capture Unit 6
72	2DC$_H$	ICU7	Yes	72	Input Capture Unit 7
73	2D8$_H$	-	-	73	Reserved
74	2D4$_H$	-	-	74	Reserved
75	2D0$_H$	-	-	75	Reserved
76	2CC$_H$	-	-	76	Reserved
77	2C8$_H$	OCU0	Yes	77	Output Compare Unit 0
78	2C4$_H$	OCU1	Yes	78	Output Compare Unit 1
79	2C0$_H$	OCU2	Yes	79	Output Compare Unit 2
80	2BC$_H$	OCU3	Yes	80	Output Compare Unit 3

Vector Number	Offset in Vector Table	Vector Name	Cleared by DMA	Index in ICR to Program	Description
81	2B8$_H$	-	-	81	Reserved
82	2B4$_H$	-	-	82	Reserved
83	2B0$_H$	-	-	83	Reserved
84	2AC$_H$	-	-	84	Reserved
85	2A8$_H$	-	-	85	Reserved
86	2A4$_H$	-	-	86	Reserved
87	2A0$_H$	-	-	87	Reserved
88	29C$_H$	-	-	88	Reserved
89	298$_H$	FRT0	Yes	89	Free-Running Timer 0
90	294$_H$	FRT1	Yes	90	Free-Running Timer 1
91	290$_H$	-	-	91	Reserved
92	28C$_H$	-	-	92	Reserved
93	288$_H$	RTC0	No	93	Real Time Clock
94	284$_H$	CAL0	No	94	Clock Calibration Unit
95	280$_H$	SG0	No	95	Sound Generator 0
96	27C$_H$	IIC0	Yes	96	I^{2}C interface 0
97	278$_H$	-	-	97	Reserved
98	274$_H$	ADC0	Yes	98	A/D Converter 0
99	270$_H$	-	-	99	Reserved
100	26C$_H$	-	-	100	Reserved
101	268$_H$	LINR0	Yes	101	LIN USART 0 RX
102	264$_H$	LINT0	Yes	102	LIN USART 0 TX
103	260$_H$	LINR1	Yes	103	LIN USART 1 RX
104	25C$_H$	LINT1	Yes	104	LIN USART 1 TX
105	258$_H$	LINR2	Yes	105	LIN USART 2 RX
106	254$_H$	LINT2	Yes	106	LIN USART 2 TX
107	250$_H$	-	-	107	Reserved
108	24C$_H$	-	-	108	Reserved
109	248$_H$	LINR4	Yes	109	LIN USART 4 RX
110	244$_H$	LINT4	Yes	110	LIN USART 4 TX
111	240$_H$	LINR5	Yes	111	LIN USART 5 RX
112	23C$_H$	LINT5	Yes	112	LIN USART 5 TX
113	238$_H$	-	-	113	Reserved
114	234$_H$	-	-	114	Reserved
115	230$_H$	-	-	115	Reserved
116	22C$_H$	-	-	116	Reserved
117	228$_H$	-	-	117	Reserved
118	224$_H$	-	-	118	Reserved
119	220$_H$	-	-	119	Reserved
120	21C$_H$	-	-	120	Reserved

Vector Number	Offset in Vector Table	Vector Name	Cleared by DMA	Index in ICR to Program	Description
121	218$_H$	SG1	No	121	Sound Generator 1
122	214$_H$	-	-	122	Reserved
123	210$_H$	-	-	123	Reserved
124	20C$_H$	-	-	124	Reserved
125	208$_H$	-	-	125	Reserved
126	204$_H$	-	-	126	Reserved
127	200$_H$	-	-	127	Reserved
128	1FC$_H$	-	-	128	Reserved
129	1F8$_H$	-	-	129	Reserved
130	1F4$_H$	-	-	130	Reserved
131	1F0$_H$	-	-	131	Reserved
132	1EC$_H$	-	-	132	Reserved
133	1E8$_H$	FLASHA	Yes	133	Flash memory A interrupt
134	1E4$_H$	-	-	134	Reserved
135	1E0$_H$	-	-	135	Reserved
136	1DC$_H$	-	-	136	Reserved
137	1D8$_H$	QPRC0	Yes	137	Quad Position/Revolution counter 0
138	1D4$_H$	QPRC1	Yes	138	Quad Position/Revolution counter 1
139	1D0$_H$	ADCRC0	No	139	A/D Converter 0 - Range Comparator
140	1CC$_H$	ADCPD0	No	140	A/D Converter 0 - Pulse detection
141	1C8$_H$	-	-	141	Reserved
142	1C4$_H$	-	-	142	Reserved
143	1C0$_H$	-	-	143	Reserved

11. Handling Precautions

Any semiconductor devices have inherently a certain rate of failure. The possibility of failure is greatly affected by the conditions in which they are used (circuit conditions, environmental conditions, etc.). This page describes precautions that must be observed to minimize the chance of failure and to obtain higher reliability from your Cypress semiconductor devices.

11.1 Precautions for Product Design
This section describes precautions when designing electronic equipment using semiconductor devices.

■Absolute Maximum Ratings

Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of certain established limits, called absolute maximum ratings. Do not exceed these ratings.

■Recommended Operating Conditions

Recommended operating conditions are normal operating ranges for the semiconductor device. All the device's electrical characteristics are warranted when operated within these ranges.

Always use semiconductor devices within the recommended operating conditions. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their sales representative beforehand.

■Processing and Protection of Pins

These precautions must be followed when handling the pins which connect semiconductor devices to power supply and input/output functions.

(1) Preventing Over-Voltage and Over-Current Conditions

Exposure to voltage or current levels in excess of maximum ratings at any pin is likely to cause deterioration within the device, and in extreme cases leads to permanent damage of the device. Try to prevent such overvoltage or over-current conditions at the design stage.

(2) Protection of Output Pins

Shorting of output pins to supply pins or other output pins, or connection to large capacitance can cause large current flows. Such conditions if present for extended periods of time can damage the device.
Therefore, avoid this type of connection.

(3) Handling of Unused Input Pins

Unconnected input pins with very high impedance levels can adversely affect stability of operation. Such pins should be connected through an appropriate resistance to a power supply pin or ground pin.

■Latch-up

Semiconductor devices are constructed by the formation of P-type and N-type areas on a substrate. When subjected to abnormally high voltages, internal parasitic PNPN junctions (called thyristor structures) may be formed, causing large current levels in excess of several hundred mA to flow continuously at the power supply pin. This condition is called latch-up.

CAUTION: The occurrence of latch-up not only causes loss of reliability in the semiconductor device, but can cause injury or damage from high heat, smoke or flame. To prevent this from happening, do the following:

(1) Be sure that voltages applied to pins do not exceed the absolute maximum ratings. This should include attention to abnormal noise, surge levels, etc.

(2) Be sure that abnormal current flows do not occur during the power-on sequence.

■Observance of Safety Regulations and Standards

Most countries in the world have established standards and regulations regarding safety, protection from electromagnetic interference, etc. Customers are requested to observe applicable regulations and standards in the design of products.

■Fail-Safe Design

Any semiconductor devices have inherently a certain rate of failure. You must protect against injury, damage or loss from such failures by incorporating safety design measures into your facility and equipment such as redundancy, fire protection, and prevention of over-current levels and other abnormal operating conditions.

■Precautions Related to Usage of Devices

Cypress semiconductor devices are intended for use in standard applications (computers, office automation and other office equipment, industrial, communications, and measurement equipment, personal or household devices, etc.).

CAUTION: Customers considering the use of our products in special applications where failure or abnormal operation may directly affect human lives or cause physical injury or property damage, or where extremely high levels of reliability are demanded (such as aerospace systems, atomic energy controls, sea floor repeaters, vehicle operating controls, medical devices for life support, etc.) are requested to consult with sales representatives before such use. The company will not be responsible for damages arising from such use without prior approval.

11.2 Precautions for Package Mounting

Package mounting may be either lead insertion type or surface mount type. In either case, for heat resistance during soldering, you should only mount under Cypress's recommended conditions. For detailed information about mount conditions, contact your sales representative.

■Lead Insertion Type

Mounting of lead insertion type packages onto printed circuit boards may be done by two methods: direct soldering on the board, or mounting by using a socket.

Direct mounting onto boards normally involves processes for inserting leads into through-holes on the board and using the flow soldering (wave soldering) method of applying liquid solder. In this case, the soldering process usually causes leads to be subjected to thermal stress in excess of the absolute ratings for storage temperature. Mounting processes should conform to Spansion recommended mounting conditions.

If socket mounting is used, differences in surface treatment of the socket contacts and IC lead surfaces can lead to contact deterioration after long periods. For this reason it is recommended that the surface treatment of socket contacts and IC leads be verified before mounting.

■Surface Mount Type

Surface mount packaging has longer and thinner leads than lead-insertion packaging, and therefore leads are more easily deformed or bent. The use of packages with higher pin counts and narrower pin pitch results in increased susceptibility to open connections caused by deformed pins, or shorting due to solder bridges.

You must use appropriate mounting techniques. Cypress recommends the solder reflow method, and has established a ranking of mounting conditions for each product. Users are advised to mount packages in accordance with Cypress ranking of recommended conditions.

■Lead-Free Packaging

CAUTION: When ball grid array (BGA) packages with Sn-Ag-Cu balls are mounted using Sn-Pb eutectic soldering, junction strength may be reduced under some conditions of use.

■Storage of Semiconductor Devices

Because plastic chip packages are formed from plastic resins, exposure to natural environmental conditions will cause absorption of moisture. During mounting, the application of heat to a package that has absorbed moisture can cause surfaces to peel, reducing moisture resistance and causing packages to crack. To prevent, do the following:

(1) Avoid exposure to rapid temperature changes, which cause moisture to condense inside the product. Store products in locations where temperature changes are slight.

(2) Use dry boxes for product storage. Products should be stored below 70% relative humidity, and at temperatures between 5°C and 30°C.
When you open Dry Package that recommends humidity 40% to 70% relative humidity.

(3) When necessary, Cypress packages semiconductor devices in highly moisture-resistant aluminum laminate bags, with a silica gel desiccant. Devices should be sealed in their aluminum laminate bags for storage.

(4) Avoid storing packages where they are exposed to corrosive gases or high levels of dust.

■Baking

Packages that have absorbed moisture may be de-moisturized by baking (heat drying). Follow the Cypress recommended conditions for baking.

Condition: 125°C/24 h

■Static Electricity

Because semiconductor devices are particularly susceptible to damage by static electricity, you must take the following precautions:

(1) Maintain relative humidity in the working environment between 40% and 70%. Use of an apparatus for ion generation may be needed to remove electricity.

(2) Electrically ground all conveyors, solder vessels, soldering irons and peripheral equipment.

(3) Eliminate static body electricity by the use of rings or bracelets connected to ground through high resistance (on the level of 1 MΩ).
Wearing of conductive clothing and shoes, use of conductive floor mats and other measures to minimize shock loads is recommended.

(4) Ground all fixtures and instruments, or protect with anti-static measures.

(5) Avoid the use of styrofoam or other highly static-prone materials for storage of completed board assemblies.

11.3 Precautions for Use Environment

Reliability of semiconductor devices depends on ambient temperature and other conditions as described above.

For reliable performance, do the following:

(1) Humidity

Prolonged use in high humidity can lead to leakage in devices as well as printed circuit boards. If high humidity levels are anticipated, consider anti-humidity processing.

(2) Discharge of Static Electricity

When high-voltage charges exist close to semiconductor devices, discharges can cause abnormal operation. In such cases, use anti-static measures or processing to prevent discharges.

(3) Corrosive Gases, Dust, or Oil

Exposure to corrosive gases or contact with dust or oil may lead to chemical reactions that will adversely affect the device. If you use devices in such conditions, consider ways to prevent such exposure or to protect the devices.

(4) Radiation, Including Cosmic Radiation

Most devices are not designed for environments involving exposure to radiation or cosmic radiation. Users should provide shielding as appropriate.

(5) Smoke, Flame

CAUTION: Plastic molded devices are flammable, and therefore should not be used near combustible substances. If devices begin to smoke or burn, there is danger of the release of toxic gases.

Customers considering the use of Cypress products in other special environmental conditions should consult with sales representatives.

12. Handling Devices

Special Care is Required for the following when Handling the Device:

• Latch-up prevention
• Unused pins handling
• External clock usage
• Notes on PLL clock mode operation
• Power supply pins (Vcc/Vss)
• Crystal oscillator and ceramic resonator circuit
• Turn on sequence of power supply to A/D converter and analog inputs
• Pin handling when not using the A/D converter
• Notes on Power-on
• Stabilization of power supply voltage
• Serial communication
• Mode Pin (MD)

1. Latch-Up Prevention

CMOS IC chips may suffer latch-up under the following conditions:
  - A voltage higher than V_{CC} or lower than V_{SS} is applied to an input or output pin.
  - A voltage higher than the rated voltage is applied between Vcc pins and Vss pins.
  - The AV_{CC} power supply is applied before the V_{CC} voltage.
Latch-up may increase the power supply current dramatically, causing thermal damages to the device.
For the same reason, extra care is required to not let the analog power-supply voltage (AV_{CC}, AVRH) exceed
the digital power-supply voltage.

2. Unused Pins Handling

Unused input pins can be left open when the input is disabled (corresponding bit of Port Input Enable register
PIER = 0).
Leaving unused input pins open when the input is enabled may result in misbehavior and possible permanent
damage of the device. To prevent latch-up, they must therefore be pulled up or pulled down through resistors which should be
more than 2kΩ.
Unused bidirectional pins can be set either to the output state and be then left open, or to the input state with
either input disabled or external pull-up/pull-down resistor as described above.

3. External Clock Usage

The permitted frequency range of an external clock depends on the oscillator type and configuration.
See AC Characteristics for detailed modes and frequency limits. Single and opposite phase external clocks must be connected as
follows:

(1) Single Phase External Clock for Main Oscillator

When using a single phase external clock for the Main oscillator, X0 pin must be driven and X1 pin left open.
And supply 1.8V power to the external clock.
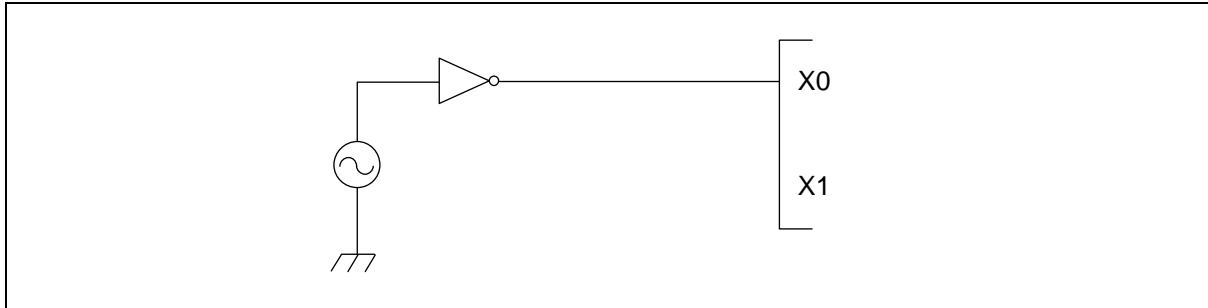
(2) Single Phase External Clock for Sub Oscillator

When using a single phase external clock for the Sub oscillator, "External clock mode" must be selected and X0A/P04_0 pin must be driven. X1A/P04_1 pin can be configured as GPIO.

(3) Opposite Phase External Clock

When using an opposite phase external clock, X1 (X1A) pins must be supplied with a clock signal which has the opposite phase to the X0 (X0A) pins. Supply level on X0 and X1 pins must be 1.8V.
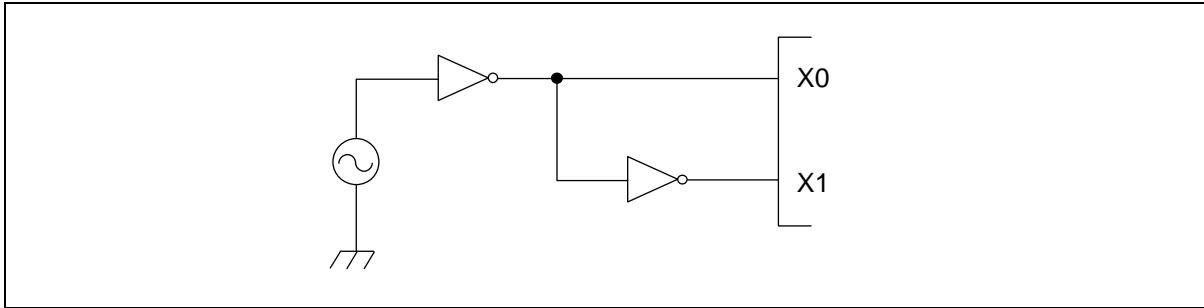
4. Notes on PLL Clock Mode Operation

If the microcontroller is operated with PLL clock mode and no external oscillator is operating or no external clock is supplied, the microcontroller attempts to work with the free oscillating PLL. Performance of this operation, however, cannot be guaranteed.

5. Power Supply Pins (Vcc/Vss)

It is required that all V_{CC}-level as well as all V_{SS}-level power supply pins are at the same potential. If there is more than one V_{CC} or V_{SS} level, the device may operate incorrectly or be damaged even within the guaranteed operating range.

Vcc and Vss pins must be connected to the device from the power supply with lowest possible impedance.

The smoothing capacitor at Vcc pin must use the one of a capacity value that is larger than Cs.

Besides this, as a measure against power supply noise, it is required to connect a bypass capacitor of about 0.1μF between Vcc and Vss pins as close as possible to Vcc and Vss pins.

6. Crystal Oscillator and ceramic resonator Circuit

Noise at X0, X1 pins or X0A, X1A pins might cause abnormal operation. It is required to provide bypass capacitors with shortest possible distance to X0, X1 pins and X0A, X1A pins, crystal oscillator (or ceramic resonator) and ground lines, and, to the utmost effort, that the lines of oscillation circuit do not cross the lines of other circuits.

It is highly recommended to provide a printed circuit board art work surrounding X0, X1 pins and X0A, X1A pins with a ground area for stabilizing the operation.

It is highly recommended to evaluate the quartz/MCU or resonator/MCU system at the quartz or resonator manufacturer, especially when using low-Q resonators at higher frequencies.

7. Turn on Sequence of Power Supply to A/D Converter and Analog Inputs

It is required to turn the A/D converter power supply (AV_{CC}, AVRH, AVRL) and analog inputs (ANn) on after turning the digital power supply (V_{CC}) on.

It is also required to turn the digital power off after turning the A/D converter supply and analog inputs off. In this case, AVRH must not exceed AV_{CC}. Input voltage for ports shared with analog input ports also must not exceed AV_{CC} (turning the analog and digital power supplies simultaneously on or off is acceptable).

8. Pin Handling when not using the A/D Converter

If the A/D converter is not used, the power supply pins for A/D converter should be connected such as $AV_{CC} = V_{CC}$, $AV_{SS} = AVRH = AVRL = V_{SS}$.

9. Notes on Power-on

To prevent malfunction of the internal voltage regulator, supply voltage profile while turning the power supply on should be slower than 50μs from 0.2V to 2.7V.

10. Stabilization of Power Supply Voltage

If the power supply voltage varies acutely even within the operation safety range of the V_{CC} power supply voltage, a malfunction may occur. The V_{CC} power supply voltage must therefore be stabilized. As stabilization guidelines, the power supply voltage must be stabilized in such a way that V_{CC} ripple fluctuations (peak to peak value) in the commercial frequencies (50Hz to 60Hz) fall within 10% of the standard V_{CC} power supply voltage and the transient fluctuation rate becomes 0.1V/μs or less in instantaneous fluctuation for power supply switching.

11. Serial Communication

There is a possibility to receive wrong data due to noise or other causes on the serial communication.
Therefore, design a printed circuit board so as to avoid noise.
Consider receiving of wrong data when designing the system. For example apply a checksum and retransmit the data if an error occurs.

12. Mode Pin (MD)

Connect the mode pin directly to Vcc or Vss pin. To prevent the device unintentionally entering test mode due to noise, lay out the printed circuit board so as to minimize the distance from the mode pin to Vcc or Vss pin and provide a low-impedance connection.

13. Electrical Characteristics

13.1 Absolute Maximum Ratings

Parameter	Symbol	Condition	Rating		Unit	Remarks
			Min	Max		
Power supply voltage*1	V_{CC}	-	V_{SS} - 0.3	V_{SS} + 6.0	V	
Analog power supply voltage*1	AV_{CC}	-	V_{SS} - 0.3	V_{SS} + 6.0	V	$V_{CC} = AV_{CC}$*2
Analog reference voltage*1	AVRH, AVRL	-	V_{SS} - 0.3	V_{SS} + 6.0	V	$AV_{CC} \geq$ AVRH, $AV_{CC} \geq$ AVRL, AVRH > AVRL, AVRL $\geq AV_{SS}$
LCD power supply voltage*1	V0 to V3	-	V_{SS} - 0.3	V_{SS} + 6.0	V	V0 to V3 must not exceed V_{CC}
Input voltage*1	V_I	-	V_{SS} - 0.3	V_{SS} + 6.0	V	$V_I \leq V_{CC}$ + 0.3V*3
Output voltage*1	V_O	-	V_{SS} - 0.3	V_{SS} + 6.0	V	$V_O \leq V_{CC}$ + 0.3V*3
Maximum Clamp Current	I_{CLAMP}	-	-4.0	+4.0	mA	Applicable to general purpose I/O pins *4
Total Maximum Clamp Current	$\Sigma|I_{CLAMP}|$	-	-	32	mA	Applicable to general purpose I/O pins *4
"L" level maximum output current	I_{OL}	-	-	15	mA	Normal port
	I_{OLHCO}	-	-	20	mA	High current port
"L" level average output current	I_{OLAV}	-	-	4	mA	Normal port
	$I_{OLAVHCO}$	-	-	15	mA	High current port
"L" level maximum overall output current	ΣI_{OL}	-	-	80	mA	Normal port
	ΣI_{OLHCO}	-	-	150	mA	High current port
"L" level average overall output current	ΣI_{OLAV}	-	-	40	mA	Normal port
	$\Sigma I_{OLAVHCO}$	-	-	100	mA	High current port
"H" level maximum output current	I_{OH}	-	-	-15	mA	Normal port
	I_{OHHCO}	-	-	-20	mA	High current port
"H" level average output current	I_{OHAV}	-	-	-4	mA	Normal port
	$I_{OHAVHCO}$	-	-	-15	mA	High current port
"H" level maximum overall output current	ΣI_{OH}	-	-	-80	mA	Normal port
	ΣI_{OHHCO}	-	-	-150	mA	High current port
"H" level average overall output current	ΣI_{OHAV}	-	-	-40	mA	Normal port
	$\Sigma I_{OHAVHCO}$	-	-	-100	mA	High current port
Power consumption*5	P_D	T_A= +125°C	-	446*6	mW	
Operating ambient temperature	T_A	-	-40	+125*7	°C	
Storage temperature	T_{STG}	-	-55	+150	°C	

*1: This parameter is based on $V_{SS} = AV_{SS} = 0V$.

*2: AV_{CC} and V_{CC} must be set to the same voltage. It is required that AV_{CC} does not exceed V_{CC} and that the voltage at the analog inputs does not exceed AV_{CC} when the power is switched on.

*3: V_I and V_O should not exceed V_{CC} + 0.3V. V_I should also not exceed the specified ratings. However if the maximum current to/from an input is limited by some means with external components, the I_{CLAMP} rating supersedes the V_I rating. Input/Output voltages of general I/O ports depend on V_{CC}.

*4: • Applicable to all general purpose I/O pins (Pnn_m).
   • Use within recommended operating conditions.

- Use at DC voltage (current).
- The +B signal should always be applied a limiting resistance placed between the +B signal and the microcontroller.
- The value of the limiting resistance should be set so that when the +B signal is applied the input current to the microcontroller pin does not exceed rated values, either instantaneously or for prolonged periods.
- Note that when the microcontroller drive current is low, such as in the power saving modes, the +B input potential may pass through the protective diode and increase the potential at the V_{CC} pin, and this may affect other devices.
- Note that if a +B signal is input when the microcontroller power supply is off (not fixed at 0V), the power supply is provided from the pins, so that incomplete operation may result.
- Note that if the +B input is applied during power-on, the power supply is provided from the pins and the resulting supply voltage may not be sufficient to operate the Power reset.
- The DEBUG I/F pin has only a protective diode against V_{SS}. Hence it is only permitted to input a negative clamping current (4mA). For protection against positive input voltages, use an external clamping diode which limits the input voltage to maximum 6.0V.

• Sample recommended circuits:
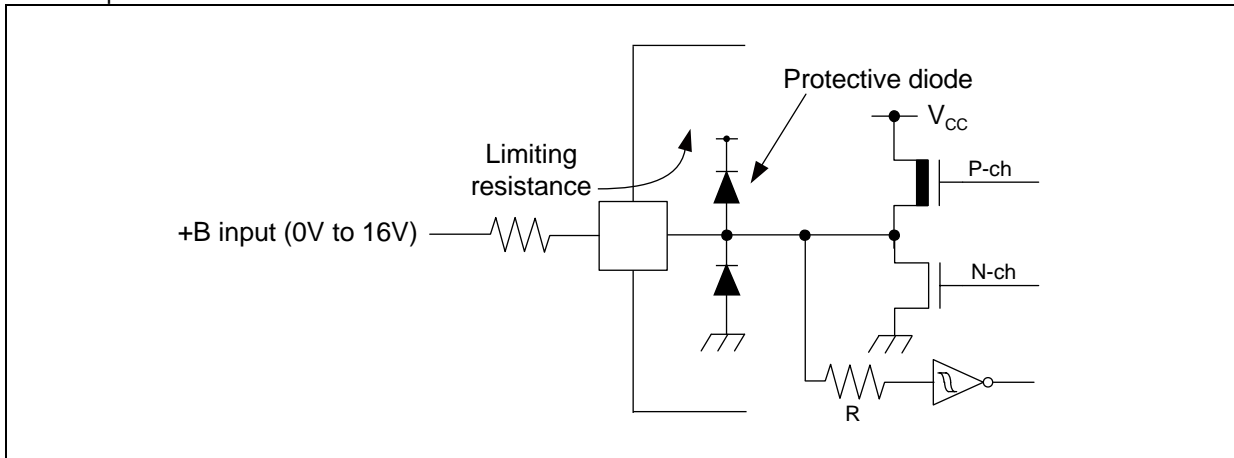
*5: The maximum permitted power dissipation depends on the ambient temperature, the air flow velocity and the thermal conductance of the package on the PCB.

The actual power dissipation depends on the customer application and can be calculated as follows:

$P_D = P_{IO} + P_{INT}$

$P_{IO} = \Sigma\ (V_{OL} \times I_{OL} + V_{OH} \times I_{OH})$ (I/O load power dissipation, sum is performed on all I/O ports)

$P_{INT} = V_{CC} \times (I_{CC} + I_A)$ (internal power dissipation)

I_{CC} is the total core current consumption into V_{CC} as described in the "DC characteristics" and depends on the selected operation mode and clock frequency and the usage of functions like Flash programming.

I_A is the analog current consumption into AV_{CC}.

*6: Worst case value for a package mounted on single layer PCB at specified T_A without air flow.

*7: Write/erase to a large sector in flash memory is warranted with $T_A \leq + 105°C$.

WARNING

Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

13.2 Recommended Operating Conditions

$(V_{SS} = AV_{SS} = 0V)$

Parameter	Symbol	Value			Unit	Remarks
		Min	Typ	Max		
Power supply voltage	V_{CC}, AV_{CC}	2.7	-	5.5	V	
		2.0	-	5.5	V	Maintains RAM data in stop mode
Smoothing capacitor at C pin	C_S	0.5	1.0 to 3.9	4.7	μF	1.0μF (Allowance within ± 50%) 3.9μF (Allowance within ± 20%) Please use the ceramic capacitor or the capacitor of the frequency response of this level. The smoothing capacitor at V_{CC} must use the one of a capacity value that is larger than C_S.

WARNING

The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges.
Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure. No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their representatives beforehand.

13.3 DC Characteristics

13.3.1 Current Rating

$(V_{CC} = AV_{CC} = 2.7V$ to $5.5V$, $V_{SS} = AV_{SS} = 0V$, $T_A = -40°C$ to $+125°C)$

Parameter	Symbol	Pin Name	Conditions	Value			Unit	Remarks
				Min	Typ	Max		
Power supply current in Run modes[1]	I_{CCPLL}	Vcc	PLL Run mode with CLKS1/2 = CLKB = CLKP1/2 = 32MHz Flash 0 wait (CLKRC and CLKSC stopped)	-	28	-	mA	$T_A = +25°C$
				-	-	38	mA	$T_A = +105°C$
				-	-	39.5	mA	$T_A = +125°C$
	I_{CCMAIN}		Main Run mode with CLKS1/2 = CLKB = CLKP1/2 = 4MHz Flash 0 wait (CLKPLL, CLKSC and CLKRC stopped)	-	3.5	-	mA	$T_A = +25°C$
				-	-	8	mA	$T_A = +105°C$
				-	-	9.5	mA	$T_A = +125°C$
	I_{CCRCH}		RC Run mode with CLKS1/2 = CLKB = CLKP1/2 = CLKRC = 2MHz Flash 0 wait (CLKMC, CLKPLL and CLKSC stopped)	-	1.8	-	mA	$T_A = +25°C$
				-	-	6	mA	$T_A = +105°C$
				-	-	7.5	mA	$T_A = +125°C$
	I_{CCRCL}		RC Run mode with CLKS1/2 = CLKB = CLKP1/2 = CLKRC = 100kHz Flash 0 wait (CLKMC, CLKPLL and CLKSC stopped)	-	0.16	-	mA	$T_A = +25°C$
				-	-	3.5	mA	$T_A = +105°C$
				-	-	5	mA	$T_A = +125°C$
	I_{CCSUB}		Sub Run mode with CLKS1/2 = CLKB = CLKP1/2 = 32kHz Flash 0 wait (CLKMC, CLKPLL and CLKRC stopped)	-	0.1	-	mA	$T_A = +25°C$
				-	-	3.3	mA	$T_A = +105°C$
				-	-	4.8	mA	$T_A = +125°C$

Parameter	Symbol	Pin Name	Conditions	Value			Unit	Remarks
				Min	Typ	Max		
Power supply current in Sleep modes[1]	I_{CCSPLL}	Vcc	PLL Sleep mode with CLKS1/2 = CLKP1/2 = 32MHz (CLKRC and CLKSC stopped)	-	9.5	-	mA	T_A = +25°C
				-	-	15	mA	T_A = +105°C
				-	-	16.5	mA	T_A = +125°C
	$I_{CCSMAIN}$		Main Sleep mode with CLKS1/2 = CLKP1/2 = 4MHz, SMCR:LPMSS = 0 (CLKPLL, CLKRC and CLKSC stopped)	-	1.1	-	mA	T_A = +25°C
				-	-	4.7	mA	T_A = +105°C
				-	-	6.2	mA	T_A = +125°C
	I_{CCSRCH}		RC Sleep mode with CLKS1/2 = CLKP1/2 = CLKRC = 2MHz, SMCR:LPMSS = 0 (CLKMC, CLKPLL and CLKSC stopped)	-	0.6	-	mA	T_A = +25°C
				-	-	4.1	mA	T_A = +105°C
				-	-	5.6	mA	T_A = +125°C
	I_{CCSRCL}		RC Sleep mode with CLKS1/2 = CLKP1/2 = CLKRC = 100kHz (CLKMC, CLKPLL and CLKSC stopped)	-	0.07	-	mA	T_A = +25°C
				-	-	2.9	mA	T_A = +105°C
				-	-	4.4	mA	T_A = +125°C
	I_{CCSSUB}		Sub Sleep mode with CLKS1/2 = CLKP1/2 = 32kHz, (CLKMC, CLKPLL and CLKRC stopped)	-	0.04	-	mA	T_A = +25°C
				-	-	2.7	mA	T_A = +105°C
				-	-	4.2	mA	T_A = +125°C

Parameter	Symbol	Pin Name	Conditions	Value			Unit	Remarks
				Min	Typ	Max		
Power supply current in Timer modes[2]	I_{CCTPLL}	Vcc	PLL Timer mode with CLKPLL = 32MHz (CLKRC and CLKSC stopped)	-	1800	2250	μA	T_A = +25°C
				-	-	3220	μA	T_A = +105°C
				-	-	4200	μA	T_A = +125°C
	$I_{CCTMAIN}$		Main Timer mode with CLKMC = 4MHz, SMCR:LPMSS = 0 (CLKPLL, CLKRC and CLKSC stopped)	-	285	330	μA	T_A = +25°C
				-	-	1200	μA	T_A = +105°C
				-	-	2155	μA	T_A = +125°C
	I_{CCTRCH}		RC Timer mode with CLKRC = 2MHz, SMCR:LPMSS = 0 (CLKPLL, CLKMC and CLKSC stopped)	-	160	215	μA	T_A = +25°C
				-	-	1110	μA	T_A = +105°C
				-	-	2065	μA	T_A = +125°C
	I_{CCTRCL}		RC Timer mode with CLKRC = 100kHz (CLKPLL, CLKMC and CLKSC stopped)	-	35	75	μA	T_A = +25°C
				-	-	910	μA	T_A = +105°C
				-	-	1870	μA	T_A = +125°C
	I_{CCTSUB}		Sub Timer mode with CLKSC = 32kHz (CLKMC, CLKPLL and CLKRC stopped)	-	25	65	μA	T_A = +25°C
				-	-	885	μA	T_A = +105°C
				-	-	1845	μA	T_A = +125°C

Parameter	Symbol	Pin Name	Conditions	Value			Unit	Remarks
				Min	Typ	Max		
Power supply current in Stop mode[3]	I_{CCH}	Vcc	-	-	20	60	μA	T_A = +25°C
				-	-	880	μA	T_A = +105°C
				-	-	1840	μA	T_A = +125°C
Flash Power Down current	$I_{CCFLASHPD}$		-	-	36	70	μA	
Power supply current for active Low Voltage detector[4]	I_{CCLVD}		Low voltage detector enabled	-	5	-	μA	T_A = +25°C
				-	-	12.5	μA	T_A = +125°C
Flash Write/ Erase current[5]	$I_{CCFLASH}$		-	-	12.5	-	mA	T_A = +25°C
				-	-	20	mA	T_A = +125°C

*1: The power supply current is measured with a 4MHz external clock connected to the Main oscillator and
    a 32kHz external clock connected to the Sub oscillator. See chapter "Standby mode and voltage regulator control circuit" of the
    Hardware Manual for further details about voltage regulator control. Current for "On Chip Debugger" part is not included. Power
    supply current in Run mode does not include Flash Write / Erase current.

*2: The power supply current in Timer mode is the value when Flash is in Power-down / reset mode.
    When Flash is not in Power-down / reset mode, $I_{CCFLASHPD}$ must be added to the Power supply current.
    The power supply current is measured with a 4MHz external clock connected to the Main oscillator and a 32kHz external clock
    connected to the Sub oscillator. The current for "On Chip Debugger" part is not included.

*3: The power supply current in Stop mode is the value when Flash is in Power-down / reset mode.
    When Flash is not in Power-down / reset mode, $I_{CCFLASHPD}$ must be added to the Power supply current.

*4: When low voltage detector is enabled, I_{CCLVD} must be added to Power supply current.

*5: When Flash Write / Erase program is executed, $I_{CCFLASH}$ must be added to Power supply current.

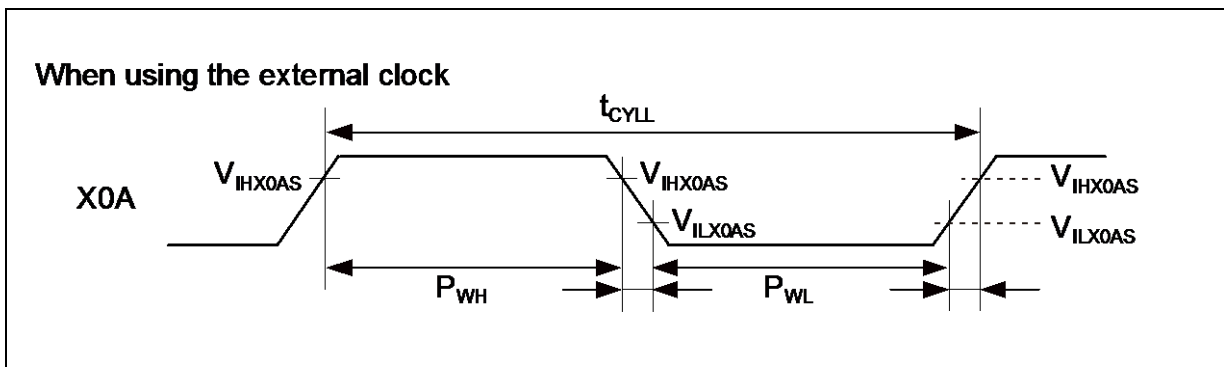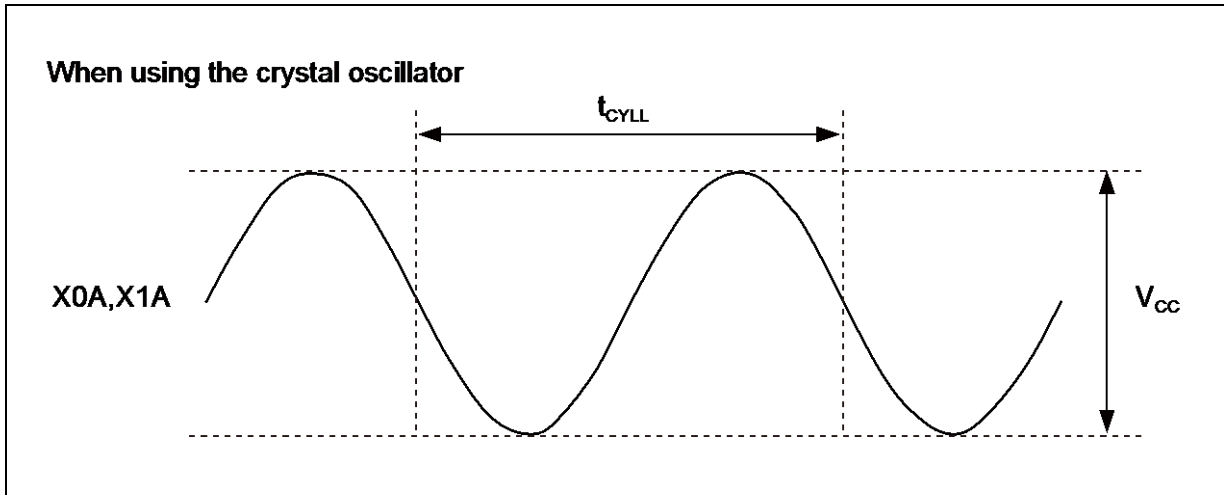### 13.3.2 Pin Characteristics

$(V_{CC} = AV_{CC} = 2.7V$ to $5.5V$, $V_{SS} = AV_{SS} = 0V$, $T_A = -40°C$ to $+125°C)$

Parameter	Symbol	Pin Name	Conditions	Value			Unit	Remarks
				Min	Typ	Max		
"H" level input voltage	V_{IH}	Port inputs Pnn_m	-	$V_{CC} \times 0.7$	-	$V_{CC} + 0.3$	V	CMOS Hysteresis input
			-	$V_{CC} \times 0.8$	-	$V_{CC} + 0.3$	V	AUTOMOTIVE Hysteresis input
	V_{IHX0S}	X0	External clock in "Fast Clock Input mode"	$VD \times 0.8$	-	VD	V	VD=1.8V±0.15V
	V_{IHX0AS}	X0A	External clock in "Oscillation mode"	$V_{CC} \times 0.8$	-	$V_{CC} + 0.3$	V	
	V_{IHR}	RSTX	-	$V_{CC} \times 0.8$	-	$V_{CC} + 0.3$	V	CMOS Hysteresis input
	V_{IHM}	MD	-	$V_{CC} - 0.3$	-	$V_{CC} + 0.3$	V	CMOS Hysteresis input
	V_{IHD}	DEBUG I/F	-	2.0	-	$V_{CC} + 0.3$	V	TTL Input
"L" level input voltage	V_{IL}	Port inputs Pnn_m	-	$V_{SS} - 0.3$	-	$V_{CC} \times 0.3$	V	CMOS Hysteresis input
			-	$V_{SS} - 0.3$	-	$V_{CC} \times 0.5$	V	AUTOMOTIVE Hysteresis input
	V_{ILX0S}	X0	External clock in "Fast Clock Input mode"	V_{SS}	-	$VD \times 0.2$	V	VD=1.8V±0.15V
	V_{ILX0AS}	X0A	External clock in "Oscillation mode"	$V_{SS} - 0.3$	-	$V_{CC} \times 0.2$	V	
	V_{ILR}	RSTX	-	$V_{SS} - 0.3$	-	$V_{CC} \times 0.2$	V	CMOS Hysteresis input
	V_{ILM}	MD	-	$V_{SS} - 0.3$	-	$V_{SS} + 0.3$	V	CMOS Hysteresis input
	V_{ILD}	DEBUG I/F	-	$V_{SS} - 0.3$	-	0.8	V	TTL Input

Parameter	Symbol	Pin Name	Conditions	Value			Unit	Remarks
				Min	Typ	Max		
"H" level output voltage	V_{OH4}	4mA type	$4.5V \leq V_{CC} \leq 5.5V$ $I_{OH} = -4mA$ $2.7V \leq V_{CC} < 4.5V$ $I_{OH} = -1.5mA$	V_{CC} - 0.5	-	V_{CC}	V	
	V_{OH20}	High Drive type*	$4.5V \leq V_{CC} \leq 5.5V$ $I_{OH} = -20mA$ $2.7V \leq V_{CC} < 4.5V$ $I_{OH} = -13mA$	V_{CC} - 0.6	-	V_{CC}	V	
	V_{OH3}	3mA type	$4.5V \leq V_{CC} \leq 5.5V$ $I_{OH} = -3mA$ $2.7V \leq V_{CC} < 4.5V$ $I_{OH} = -1.5mA$	V_{CC} - 0.5	-	V_{CC}	V	
"L" level output voltage	V_{OL4}	4mA type	$4.5V \leq V_{CC} \leq 5.5V$ $I_{OL} = +4mA$ $2.7V \leq V_{CC} < 4.5V$ $I_{OL} = +1.7mA$	-	-	0.4	V	
	V_{OL20}	High Drive type*	$4.5V \leq V_{CC} \leq 5.5V$ $I_{OL} = +20mA$ $2.7V \leq V_{CC} < 4.5V$ $I_{OL} = +13mA$	-	-	0.6	V	
	V_{OL3}	3mA type	$2.7V \leq V_{CC} < 5.5V$ $I_{OL} = +3mA$	-	-	0.4	V	
	V_{OLD}	DEBUG I/F	$V_{CC} = 2.7V$ $I_{OL} = +25mA$	0	-	0.25	V	

Parameter	Symbol	Pin Name	Conditions	Value			Unit	Remarks
				Min	Typ	Max		
Input leak current	I_{IL}	Pnn_m	$V_{SS} < V_I < V_{CC}$ AV_{SS}, AVRL $< V_I < AV_{CC}$, AVRH	- 1	-	+ 1	μA	
		P08_m, P09_m, P10_m	$V_{SS} < V_I < V_{CC}$ $AV_{SS,}$ AVRL $< V_I < AV_{CC}$, AVRH	- 3	-	+ 3	μA	
Total LCD leak current	$\Sigma|I_{ILCD}|$	All SEG/ COM pin	$V_{CC} = 5.0V$	-	0.5	10	μA	Maximum leakage current of all LCD pins
Internal LCD divide resistance	R_{LCD}	Between V3 and V2, V2 and V1, V1 and V0	$V_{CC} = 5.0V$	6.25	12.5	25	kΩ	
Pull-up resistance value	R_{PU}	Pnn_m	$V_{CC} = 5.0V$ ±10%	25	50	100	kΩ	
Input capacitance	C_{IN}	Other than C, Vcc, Vss, AVcc, AVss, AVRH, AVRL, P08_m, P09_m, P10_m	-	-	5	15	pF	
		P08_m, P09_m, P10_m	-	-	15	30	pF	

*: In the case of high current outputs, set "1" to the bit in the Port High Drive Register.

13.4 AC Characteristics

13.4.1 Main Clock Input Characteristics

$(V_{CC} = AV_{CC} = 2.7V$ to $5.5V$, $VD=1.8V\pm0.15V$, $V_{SS} = AV_{SS} = 0V$, $T_A = -40°C$ to $+125°C)$

Parameter	Symbol	Pin Name	Value			Unit	Remarks
			Min	Typ	Max		
Input frequency	f_C	X0, X1	4	-	8	MHz	When using a crystal oscillator, PLL off
			-	-	8	MHz	When using an opposite phase external clock, PLL off
			4	-	8	MHz	When using a crystal oscillator or opposite phase external clock, PLL on
Input frequency	f_{FCI}	X0	-	-	8	MHz	When using a single phase external clock in "Fast Clock Input mode", PLL off
			4	-	8	MHz	When using a single phase external clock in "Fast Clock Input mode", PLL on
Input clock cycle	t_{CYLH}	-	125	-	-	ns	
Input clock pulse width	P_{WH}, P_{WL}	-	55	-	-	ns	

When using the crystal oscillator

t_{CYLH}

X0,X1

Reference value: 1.8V±0.15V

The amplitude changes by resistance, capacity which added outside or the difference of the device.

When using the external clock
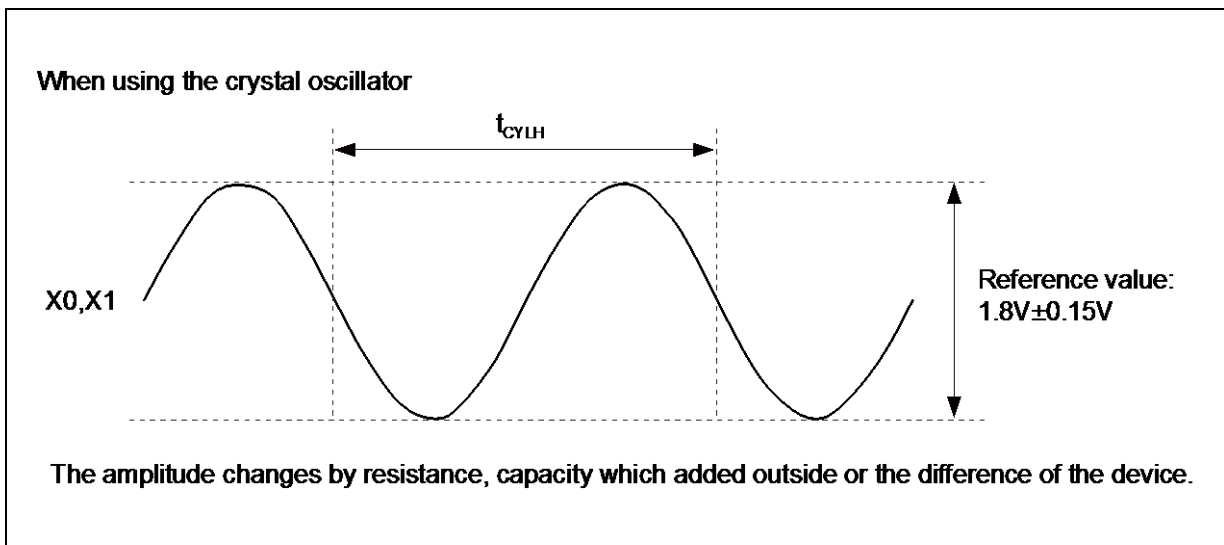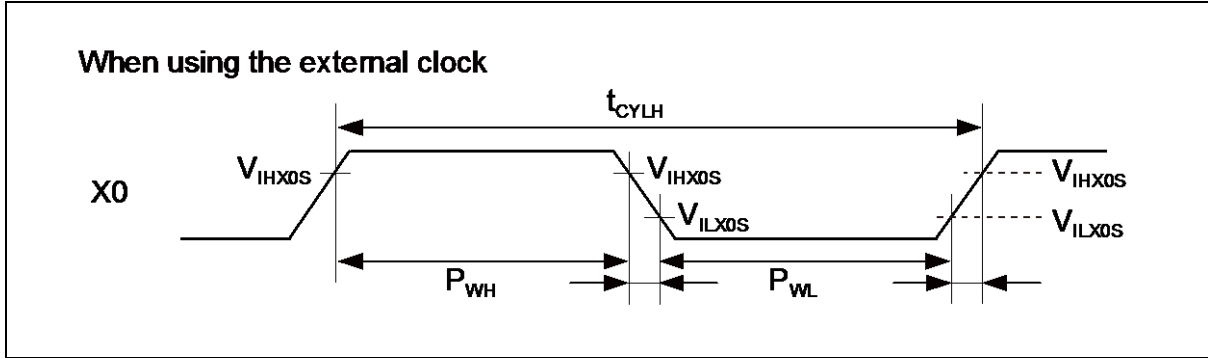
13.4.2 Sub Clock Input Characteristics

$(V_{CC} = AV_{CC} = 2.7V \text{ to } 5.5V, V_{SS} = AV_{SS} = 0V, T_A = -40°C \text{ to } +125°C)$

Parameter	Symbol	Pin Name	Conditions	Value			Unit	Remarks
				Min	Typ	Max		
Input frequency	f_{CL}	X0A, X1A	-	-	32.768	-	kHz	When using an oscillation circuit
			-	-	-	100	kHz	When using an opposite phase external clock
		X0A	-	-	-	50	kHz	When using a single phase external clock
Input clock cycle	t_{CYLL}	-	-	10	-	-	μs	
Input clock pulse width	-	-	P_{WH}/t_{CYLL}, P_{WL}/t_{CYLL}	30	-	70	%	

When using the crystal oscillator

When using the external clock

13.4.3 Built-in RC Oscillation Characteristics

(V$_{CC}$ = AV$_{CC}$ = 2.7V to 5.5V, V$_{SS}$ = AV$_{SS}$ = 0V, T$_A$ = - 40°C to + 125°C)

Parameter	Symbol	Value			Unit	Remarks
		Min	Typ	Max		
Clock frequency	f$_{RC}$	50	100	200	kHz	When using slow frequency of RC oscillator
		1	2	4	MHz	When using fast frequency of RC oscillator
RC clock stabilization time	t$_{RCSTAB}$	80	160	320	μs	When using slow frequency of RC oscillator (16 RC clock cycles)
		64	128	256	μs	When using fast frequency of RC oscillator (256 RC clock cycles)

13.4.4 Internal Clock Timing

(V$_{CC}$ = AV$_{CC}$ = 2.7V to 5.5V, V$_{SS}$ = AV$_{SS}$ = 0V, T$_A$ = - 40°C to + 125°C)

Parameter	Symbol	Value		Unit
		Min	Max	
Internal System clock frequency (CLKS1 and CLKS2)	f$_{CLKS1}$, f$_{CLKS2}$	-	54	MHz
Internal CPU clock frequency (CLKB), Internal peripheral clock frequency (CLKP1)	f$_{CLKB}$, f$_{CLKP1}$	-	32	MHz
Internal peripheral clock frequency (CLKP2)	f$_{CLKP2}$	-	32	MHz

13.4.5 Operating Conditions of PLL

$(V_{CC} = AV_{CC} = 2.7V$ to $5.5V$, $V_{SS} = AV_{SS} = 0V$, $T_A = -40°C$ to $+125°C)$

Parameter	Symbol	Value			Unit	Remarks
		Min	Typ	Max		
PLL oscillation stabilization wait time	t_{LOCK}	1	-	4	ms	For CLKMC = 4MHz
PLL input clock frequency	f_{PLLI}	4	-	8	MHz	
PLL oscillation clock frequency	f_{CLKVCO}	56	-	108	MHz	Permitted VCO output frequency of PLL (CLKVCO)
PLL phase jitter	t_{PSKEW}	-5	-	+5	ns	For CLKMC (PLL input clock) ≥ 4MHz

Deviation time from the ideal clock is assured per cycle out of 20,000 cycles.
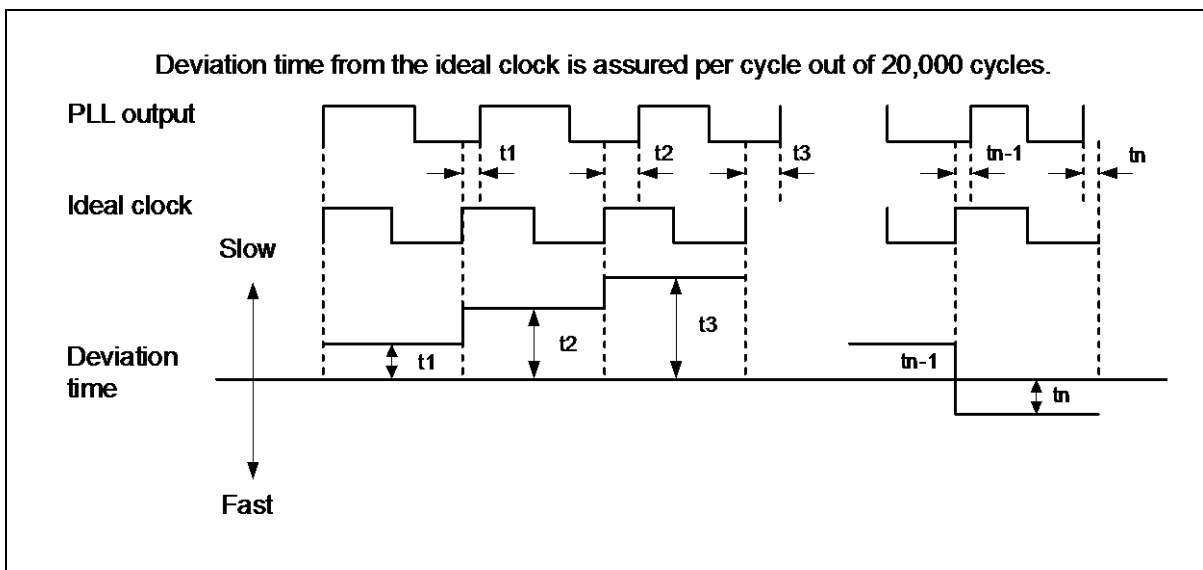
13.4.6 Reset Input

$(V_{CC} = AV_{CC} = 2.7V$ to $5.5V$, $V_{SS} = AV_{SS} = 0V$, $T_A = -40°C$ to $+125°C)$

Parameter	Symbol	Pin Name	Value		Unit
			Min	Max	
Reset input time	t_{RSTL}	RSTX	10	-	µs
Rejection of reset input time			1	-	µs
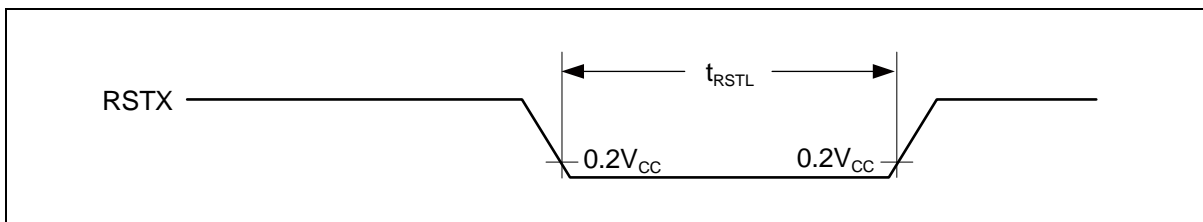
13.4.7 Power-on Reset Timing

$(V_{CC} = AV_{CC} = 2.7V$ to $5.5V$, $V_{SS} = AV_{SS} = 0V$, $T_A = -40°C$ to $+125°C)$

Parameter	Symbol	Pin Name	Value			Unit
			Min	Typ	Max	
Power on rise time	t_R	Vcc	0.05	-	30	ms
Power off time	t_{OFF}	Vcc	1	-	-	ms

If the power supply is changed too rapidly, a power-on reset may occur. We recommend a smooth startup by restraining voltages when changing the power supply voltage during operation, as shown in the figure below.

It is required that rises in voltage have a slope of 50 mV/ms or less.
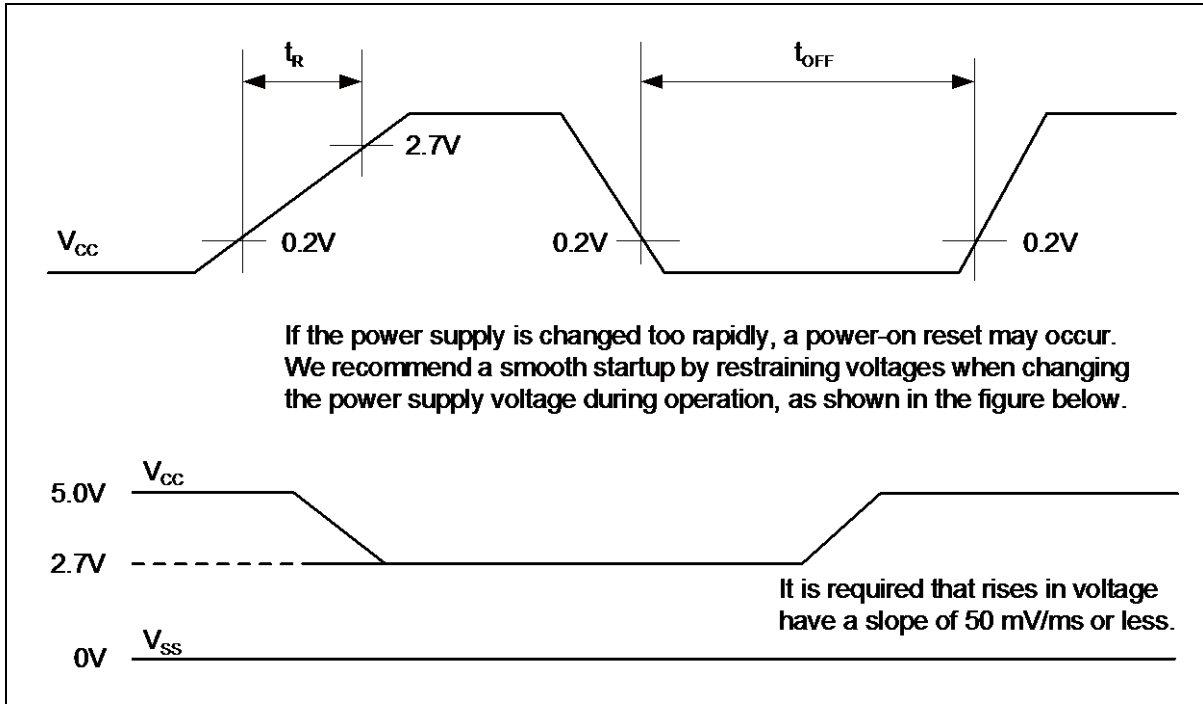
13.4.8 USART Timing

(V_{CC} = AV_{CC} = 2.7V to 5.5V, V_{SS} = AV_{SS} = 0V, T_A = - 40°C to + 125°C, C_L=50pF)

Parameter	Symbol	Pin Name	Conditions	$4.5V \leq V_{CC} < 5.5V$ Min	Max	$2.7V \leq V_{CC} < 4.5V$ Min	Max	Unit
Serial clock cycle time	t_{SCYC}	SCKn	Internal shift clock mode	$4t_{CLKP1}$	-	$4t_{CLKP1}$	-	ns
SCK ↓ → SOT delay time	t_{SLOVI}	SCKn, SOTn		- 20	+ 20	- 30	+ 30	ns
SOT → SCK ↑ delay time	t_{OVSHI}	SCKn, SOTn		$N \times t_{CLKP1} - 20^*$	-	$N \times t_{CLKP1} - 30^*$	-	ns
SIN → SCK ↑ setup time	t_{IVSHI}	SCKn, SINn		$t_{CLKP1} + 45$	-	$t_{CLKP1} + 55$	-	ns
SCK ↑ → SIN hold time	t_{SHIXI}	SCKn, SINn		0	-	0	-	ns
Serial clock "L" pulse width	t_{SLSH}	SCKn	External shift clock mode	$t_{CLKP1} + 10$	-	$t_{CLKP1} + 10$	-	ns
Serial clock "H" pulse width	t_{SHSL}	SCKn		$t_{CLKP1} + 10$	-	$t_{CLKP1} + 10$	-	ns
SCK ↓ → SOT delay time	t_{SLOVE}	SCKn, SOTn		-	$2t_{CLKP1} + 45$	-	$2t_{CLKP1} + 55$	ns
SIN → SCK ↑ setup time	t_{IVSHE}	SCKn, SINn		$t_{CLKP1}/2 + 10$	-	$t_{CLKP1}/2 + 10$	-	ns
SCK ↑ → SIN hold time	t_{SHIXE}	SCKn, SINn		$t_{CLKP1} + 10$	-	$t_{CLKP1} + 10$	-	ns
SCK fall time	t_F	SCKn		-	20	-	20	ns
SCK rise time	t_R	SCKn		-	20	-	20	ns

Notes:
- AC characteristic in CLK synchronized mode.
- CL is the load capacity value of pins when testing.
- Depending on the used machine clock frequency, the maximum possible baud rate can be limited by   some parameters. These parameters are shown in "CY96600 series HARDWARE MANUAL".
- t_{CLKP1} indicates the peripheral clock 1 (CLKP1), Unit: ns
- These characteristics only guarantee the same relocate port number.
  For example, the combination of SCKn and SOTn_R is not guaranteed.

*: Parameter N depends on t_{SCYC} and can be calculated as follows:

- If $t_{SCYC} = 2 \times k \times t_{CLKP1}$, then N = k, where k is an integer > 2

- If $t_{SCYC} = (2 \times k + 1) \times t_{CLKP1}$, then N = k + 1, where k is an integer > 1

Examples:

t_{SCYC}	N
$4 \times t_{CLKP1}$	2
$5 \times t_{CLKP1}$, $6 \times t_{CLKP1}$	3
$7 \times t_{CLKP1}$, $8 \times t_{CLKP1}$	4
...	...

Internal shift clock mode

External shift clock mode
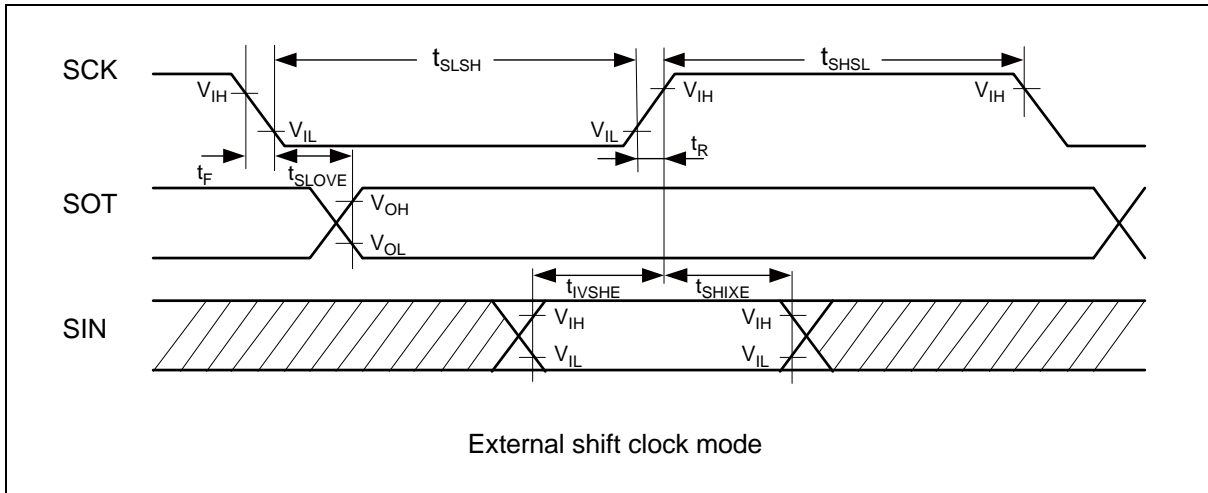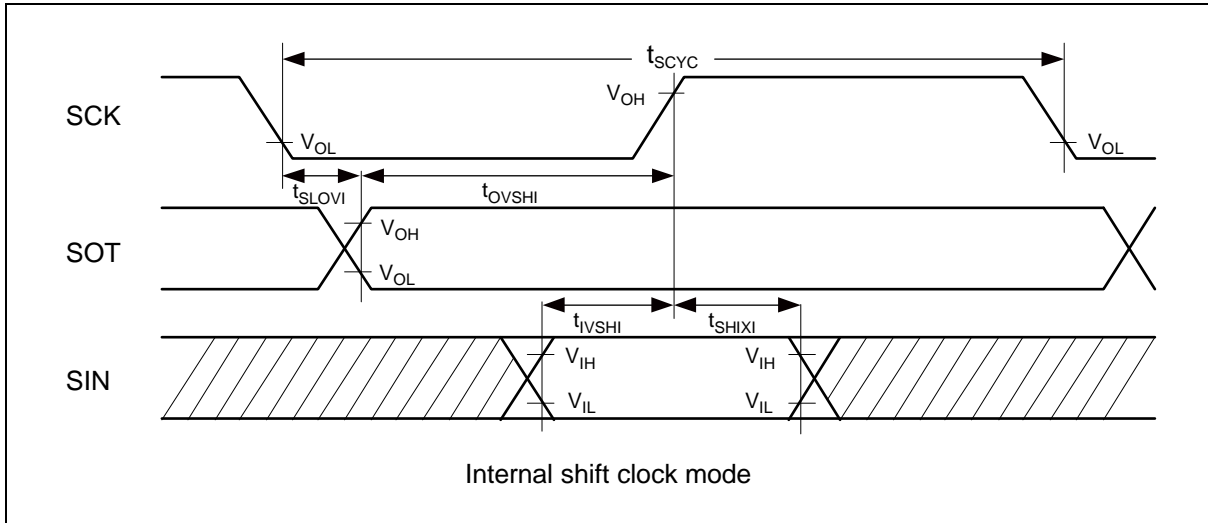
13.4.9 External Input Timing

$(V_{CC} = AV_{CC} = 2.7V \text{ to } 5.5V, V_{SS} = AV_{SS} = 0V, T_A = -40°C \text{ to } +125°C)$

Parameter	Symbol	Pin Name	Value		Unit	Remarks
			Min	Max		
Input pulse width	t_{INH}, t_{INL}	Pnn_m	$2t_{CLKP1} +200$ ($t_{CLKP1}=$ $1/f_{CLKP1}$)*	-	ns	General Purpose I/O
		ADTG				A/D Converter trigger input
		TINn, TINn_R				Reload Timer
		TTGn				PPG trigger input
		FRCKn, FRCKn_R				Free-Running Timer input clock
		INn, INn_R				Input Capture
		AINn, BINn, ZINn				Quadrature Position/Revolution Counter
		INTn, INTn_R	200	-	ns	External Interrupt
		NMI				Non-Maskable Interrupt

*: t_{CLKP1} indicates the peripheral clock1 (CLKP1) cycle time except stop when in stop mode.

External input timing — V_{IH}, V_{IH}, t_{INH}, V_{IL}, V_{IL}, t_{INL}
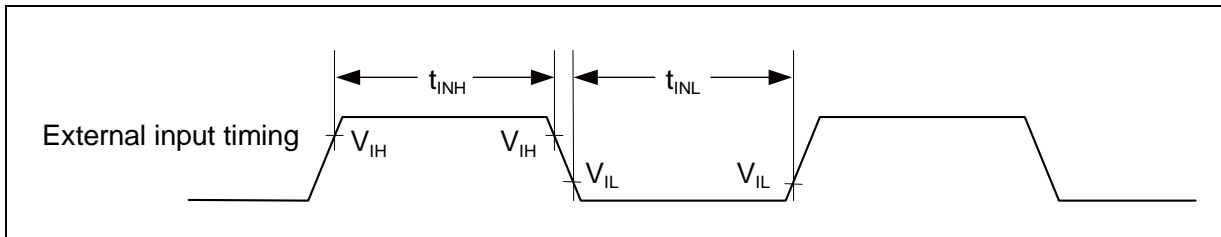
13.4.10 I²C Timing

(V$_{CC}$ = AV$_{CC}$ = 2.7V to 5.5V, V$_{SS}$ = AV$_{SS}$ = 0V, T$_A$ = - 40°C to + 125°C)

Parameter	Symbol	Conditions	Typical Mode		High-Speed Mode*4		Unit
			Min	Max	Min	Max	
SCL clock frequency	f$_{SCL}$		0	100	0	400	kHz
(Repeated) START condition hold time SDA↓→SCL↓	t$_{HDSTA}$		4.0	-	0.6	-	µs
SCL clock "L" width	t$_{LOW}$		4.7	-	1.3	-	µs
SCL clock "H" width	t$_{HIGH}$		4.0	-	0.6	-	µs
(Repeated) START condition setup time SCL↑→SDA↓	t$_{SUSTA}$	C$_L$ = 50pF, R = (Vp/I$_{OL}$)*1	4.7	-	0.6	-	µs
Data hold time SCL↓→SDA↓↑	t$_{HDDAT}$		0	3.45*2	0	0.9*3	µs
Data setup time SDA↓↑→SCL↑	t$_{SUDAT}$		250	-	100	-	ns
STOP condition setup time SCL↑→SDA↑	t$_{SUSTO}$		4.0	-	0.6	-	µs
Bus free time between "STOP condition" and "START condition"	t$_{BUS}$		4.7	-	1.3	-	µs
Pulse width of spikes which will be suppressed by input noise filter	t$_{SP}$	-	0	(1-1.5) × t$_{CLKP1}$*5	0	(1-1.5) × t$_{CLKP1}$*5	ns

*1: R and C$_L$ represent the pull-up resistance and load capacitance of the SCL and SDA lines, respectively.
   Vp indicates the power supply voltage of the pull-up resistance and I$_{OL}$ indicates V$_{OL}$ guaranteed current.

*2: The maximum t$_{HDDAT}$ only has to be met if the device does not extend the "L" width (t$_{LOW}$) of the SCL signal.

*3: A high-speed mode I²C bus device can be used on a standard mode I²C bus system as long as the device satisfies the requirement of "t$_{SUDAT}$ ≥ 250ns".

*4: For use at over 100kHz, set the peripheral clock1 (CLKP1) to at least 6MHz.

*5: t$_{CLKP1}$ indicates the peripheral clock1 (CLKP1) cycle time.
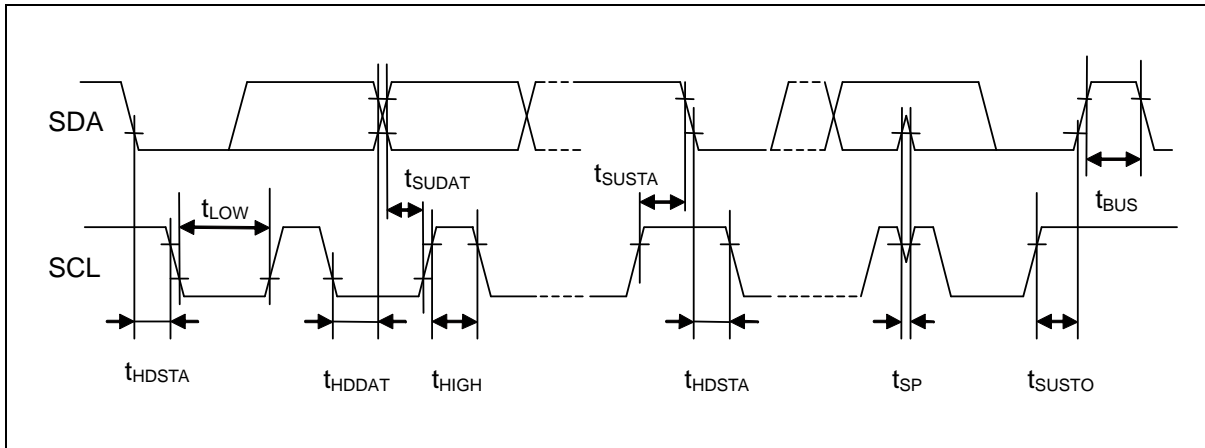
13.5 A/D Converter

13.5.1 Electrical Characteristics for the A/D Converter

$(V_{CC} = AV_{CC} = 2.7V$ to $5.5V$, $V_{SS} = AV_{SS} = 0V$, $T_A = -40°C$ to $+125°C$)

Parameter	Symbol	Pin Name	Value			Unit	Remarks
			Min	Typ	Max		
Resolution	-	-	-	-	10	bit	
Total error	-	-	- 3.0	-	+ 3.0	LSB	
Nonlinearity error	-	-	- 2.5	-	+ 2.5	LSB	
Differential Nonlinearity error	-	-	- 1.9	-	+ 1.9	LSB	
Zero transition voltage	V_{OT}	ANn	Typ - 20	AVRL + 0.5LSB	Typ + 20	mV	
Full scale transition voltage	V_{FST}	ANn	Typ - 20	AVRH - 1.5LSB	Typ + 20	mV	
Compare time*	-	-	1.0	-	5.0	μs	$4.5V \le AV_{CC} \le 5.5V$
			2.2	-	8.0	μs	$2.7V \le AV_{CC} < 4.5V$
Sampling time*	-	-	0.5	-	-	μs	$4.5V \le AV_{CC} \le 5.5V$
			1.2	-	-	μs	$2.7V \le AV_{CC} < 4.5V$
Power supply current	I_A	AV_{CC}	-	2.0	3.1	mA	A/D Converter active
	I_{AH}		-	-	3.3	μA	A/D Converter not operated
Reference power supply current (between AVRH and AVRL)	I_R	AVRH	-	520	810	μA	A/D Converter active
	I_{RH}		-	-	1.0	μA	A/D Converter not operated
Analog input capacity	C_{VIN}	AN0 to 15	-	-	16.0	pF	Normal outputs
		AN16 to 31	-	-	17.8	pF	High current outputs
Analog impedance	R_{VIN}	ANn	-	-	2050	Ω	$4.5V \le AV_{CC} \le 5.5V$
			-	-	3600	Ω	$2.7V \le AV_{CC} < 4.5V$
Analog port input current (during conversion)	I_{AIN}	AN0 to 15	- 0.3	-	+ 0.3	μA	AV_{SS} , AVRL $< V_{AIN} <$ AV_{CC}, AVRH
		AN16 to 31	- 3.0	-	+ 3.0	μA	
Analog input voltage	V_{AIN}	ANn	AVRL	-	AVRH	V	
Reference voltage range	-	AVRH	AV_{CC} - 0.1	-	AV_{CC}	V	
	-	AVRL	AV_{SS}	-	AV_{SS} + 0.1	V	
Variation between channels	-	ANn	-	-	4.0	LSB	

*: Time for each channel.

13.5.2 Accuracy and Setting of the A/D Converter Sampling Time

If the external impedance is too high or the sampling time too short, the analog voltage charged to the internal sample and hold capacitor is insufficient, adversely affecting the A/D conversion precision.

To satisfy the A/D conversion precision, a sufficient sampling time must be selected. The required sampling time (Tsamp) depends on the external driving impedance R_{ext}, the board capacitance of the A/D converter input pin C_{ext} and the AV_{CC} voltage level. The following replacement model can be used for the calculation:
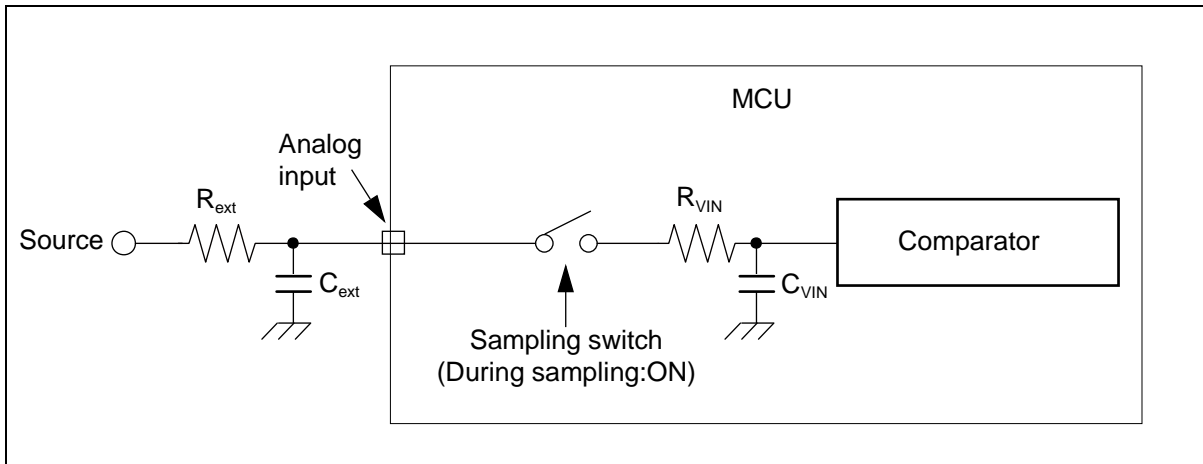
R_{ext}: External driving impedance

C_{ext}: Capacitance of PCB at A/D converter input

C_{VIN}: Analog input capacity (I/O, analog switch and ADC are contained)

R_{VIN}: Analog input impedance (I/O, analog switch and ADC are contained)

The following approximation formula for the replacement model above can be used:

$$Tsamp = 7.62 \times (Rext \times Cext + (Rext + R_{VIN}) \times C_{VIN})$$

■ Do not select a sampling time below the absolute minimum permitted value.
   (0.5μs for 4.5V ≤ AV_{CC} ≤ 5.5V, 1.2μs for 2.7V ≤ AV_{CC} < 4.5V)

■ If the sampling time cannot be sufficient, connect a capacitor of about 0.1μF to the analog input pin.

■ A big external driving impedance also adversely affects the A/D conversion precision due to the pin input leakage current IIL (static current before the sampling switch) or the analog input leakage current IAIN (total leakage current of pin input and comparator during sampling). The effect of the pin input leakage current IIL cannot be compensated by an external capacitor.

■ The accuracy gets worse as |AVRH - AVRL| becomes smaller.

13.5.3 Definition of A/D Converter Terms

Resolution : Analog variation that is recognized by an A/D converter.

Nonlinearity error : Deviation of the actual conversion characteristics from a straight line that connects the zero transition point (0b0000000000 ←→ 0b0000000001) to the full-scale transition point (0b1111111110 ←→ 0b1111111111).

Differential nonlinearity error : Deviation from the ideal value of the input voltage that is required to change the output code by 1LSB.

Total error : Difference between the actual value and the theoretical value. The total error includes zero transition error, full-scale transition error and nonlinearity error.

Zero transition voltage: Input voltage which results in the minimum conversion value.

Full scale transition voltage: Input voltage which results in the maximum conversion value.

$$\text{Nonlinearity error of digital output N} = \frac{V_{NT} - \{1LSB \times (N - 1) + V_{OT}\}}{1LSB} \ [\text{LSB}]$$

$$\text{Differential nonlinearity error of digital output N} = \frac{V_{(N + 1) T} - V_{NT}}{1LSB} - 1 \ [\text{LSB}]$$

$$1LSB = \frac{V_{FST} - V_{OT}}{1022}$$

N   : A/D converter digital output value.
V_{OT} : Voltage at which the digital output changes from 0x000 to 0x001.
V_{FST} : Voltage at which the digital output changes from 0x3FE to 0x3FF.
V_{NT} : Voltage at which the digital output changes from 0x(N − 1) to 0xN.

$$1\text{LSB (Ideal value)} = \frac{AVRH - AVRL}{1024} \ [V]$$

$$\text{Total error of digital output } N = \frac{V_{NT} - \{1LSB \times (N - 1) + 0.5LSB\}}{1LSB}$$

N   : A/D converter digital output value.

V_{NT} : Voltage at which the digital output changes from 0x(N + 1) to 0xN.

V_{OT} (Ideal value) = AVRL + 0.5LSB[V]

V_{FST} (Ideal value) = AVRH - 1.5LSB[V]

13.6 High Current Output Slew Rate

$(V_{CC} = AV_{CC} = 2.7V$ to $5.5V$, $V_{SS} = AV_{SS} = 0V$, $T_A = -40°C$ to $+125°C)$

Parameter	Symbol	Pin Name	Conditions	Value			Unit	Remarks
				Min	Typ	Max		
Output rise/fall time	t_{R20}, t_{F20}	P08_m, P09_m, P10_m	Outputs driving strength set to "20mA"	15	-	75	ns	C_L=85pF

$V_H = V_{OL20} + 0.9 \times (V_{OH20} - V_{OL20})$
$V_L = V_{OL20} + 0.1 \times (V_{OH20} - V_{OL20})$
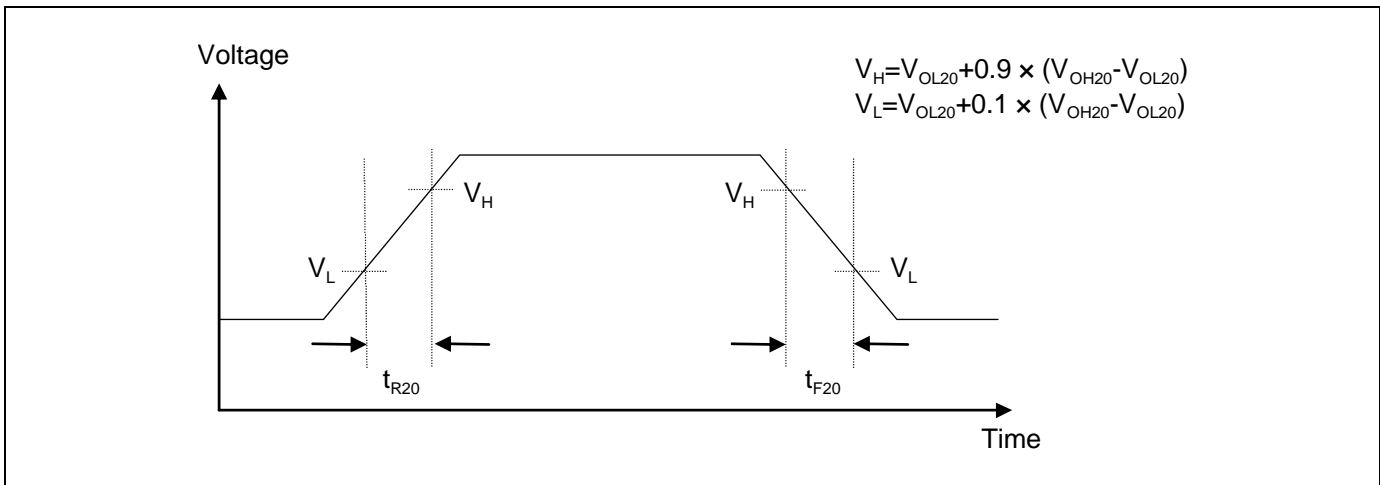
13.7 Low Voltage Detection Function Characteristics

$(V_{CC} = AV_{CC} = 2.7V$ to $5.5V$, $V_{SS} = AV_{SS} = 0V$, $T_A = -40°C$ to $+125°C)$

Parameter	Symbol	Conditions	Value			Unit
			Min	Typ	Max	
Detected voltage[1]	V_{DL0}	CILCR:LVL = 0000B	2.70	2.90	3.10	V
	V_{DL1}	CILCR:LVL = 0001B	2.79	3.00	3.21	V
	V_{DL2}	CILCR:LVL = 0010B	2.98	3.20	3.42	V
	V_{DL3}	CILCR:LVL = 0011B	3.26	3.50	3.74	V
	V_{DL4}	CILCR:LVL = 0100B	3.45	3.70	3.95	V
	V_{DL5}	CILCR:LVL = 0111B	3.73	4.00	4.27	V
	V_{DL6}	CILCR:LVL = 1001B	3.91	4.20	4.49	V
Power supply voltage change rate[2]	dV/dt	-	- 0.004	-	+ 0.004	V/μs
Hysteresis width	V_{HYS}	CILCR:LVHYS=0	-	-	50	mV
		CILCR:LVHYS=1	80	100	120	mV
Stabilization time	$T_{LVDSTAB}$	-	-	-	75	μs
Detection delay time	t_d	-	-	-	30	μs

[1]: If the power supply voltage fluctuates within the time less than the detection delay time (t_d), there is a possibility that the low voltage detection will occur or stop after the power supply voltage passes the detection range.

[2]: In order to perform the low voltage detection at the detection voltage (V_{DLX}), be sure to suppress fluctuation of the power supply voltage within the limits of the change ration of power supply voltage.
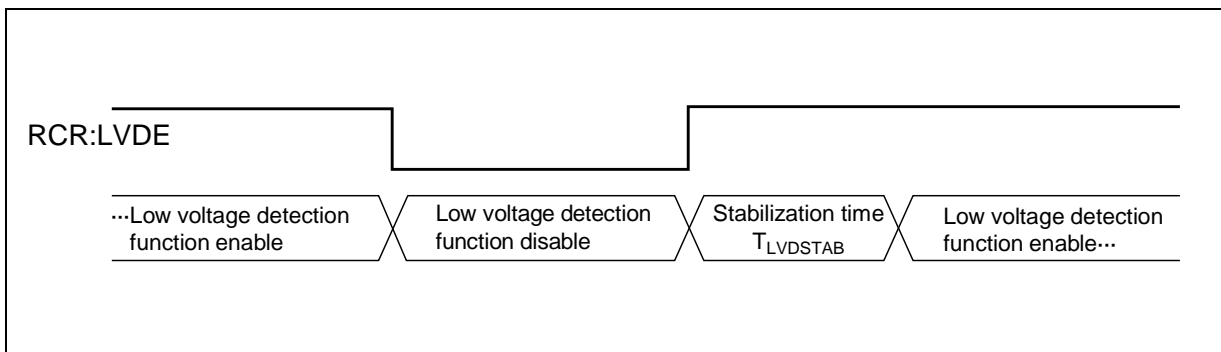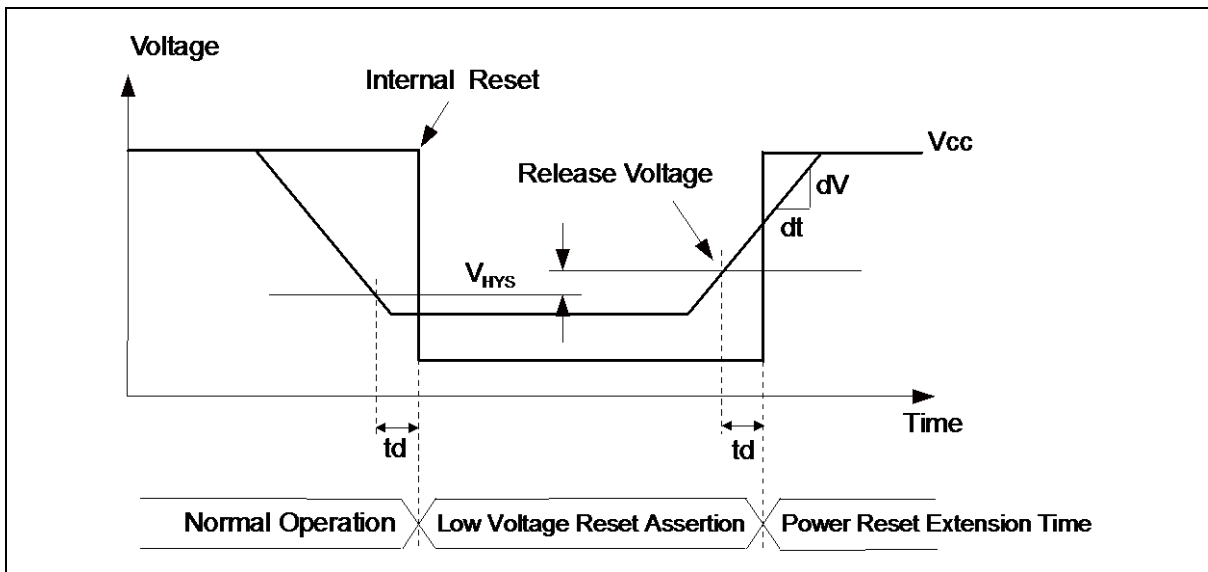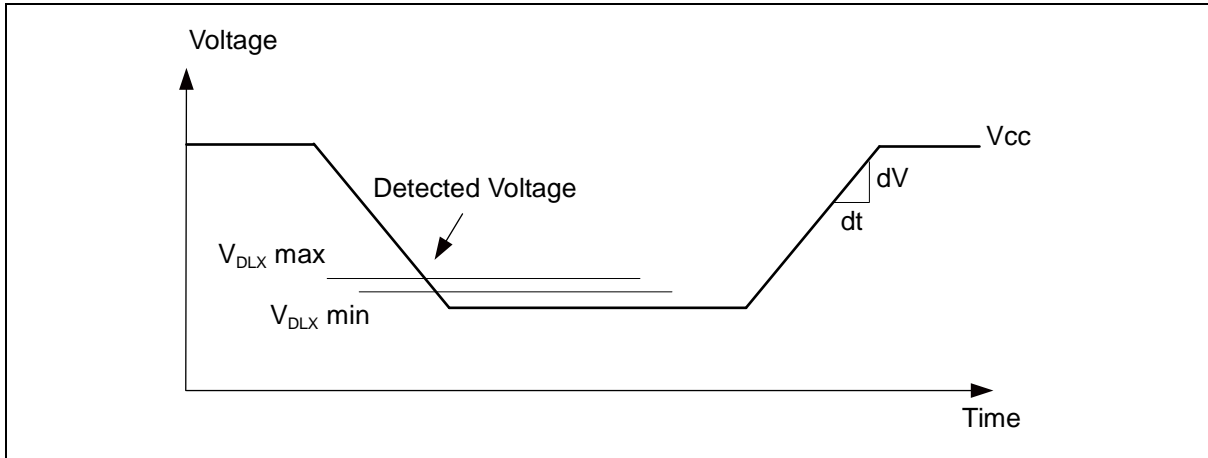
13.8 Flash Memory Write/Erase Characteristics

$(V_{CC} = AV_{CC} = 2.7V\ to\ 5.5V,\ V_{SS} = AV_{SS} = 0V,\ T_A = -40°C\ to\ +125°C)$

Parameter		Conditions	Value			Unit	Remarks
			Min	Typ	Max		
Sector erase time	Large Sector	$T_A ≤ +105°C$	-	1.6	7.5	s	Includes write time prior to internal erase.
	Small Sector	-	-	0.4	2.1	s	
	Security Sector	-	-	0.31	1.65	s	
Word (16-bit) write time	Large Sector	$T_A ≤ +105°C$	-	25	400	μs	Not including system-level overhead time.
	Small Sector	-	-	25	400	μs	
Chip erase time		$T_A ≤ +105°C$	-	8.31	40.05	s	Includes write time prior to internal erase.

Note: While the Flash memory is written or erased, shutdown of the external power (V_{CC}) is prohibited. In the application system where the external power (V_{CC}) might be shut down while writing or erasing, be sure to turn the power off by using a low voltage detection function.

To put it concrete, change the external power in the range of change ration of power supply voltage (-0.004V/μs to +0.004V/μs) after the external power falls below the detection voltage (V_{DLX})[1].

Write/Erase cycles and data hold time

Write/Erase Cycles (Cycle)	Data Hold Time (Year)
1,000	20 [2]
10,000	10 [2]
100,000	5 [2]

*1: See "14.7. Low Voltage Detection Function Characteristics".

*2: This value comes from the technology qualification (using Arrhenius equation to translate high temperature measurements into normalized value at +85°C).

14. Example Characteristics

This characteristic is an actual value of the arbitrary sample. It is not the guaranteed value.

CY96F6C6

Run Mode
(V_{CC} = 5.5V)

Sleep Mode
(V_{CC} = 5.5V)

CY96F6C6

Timer Mode

$(V_{CC} = 5.5V)$

Stop Mode

$(V_{CC} = 5.5V)$
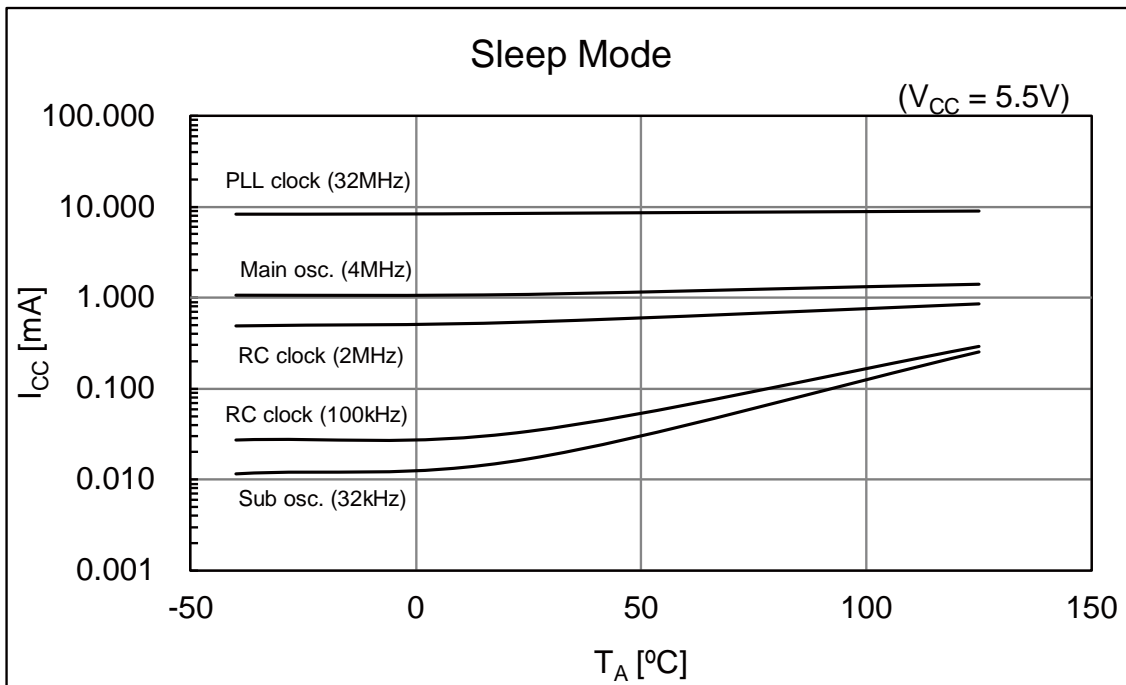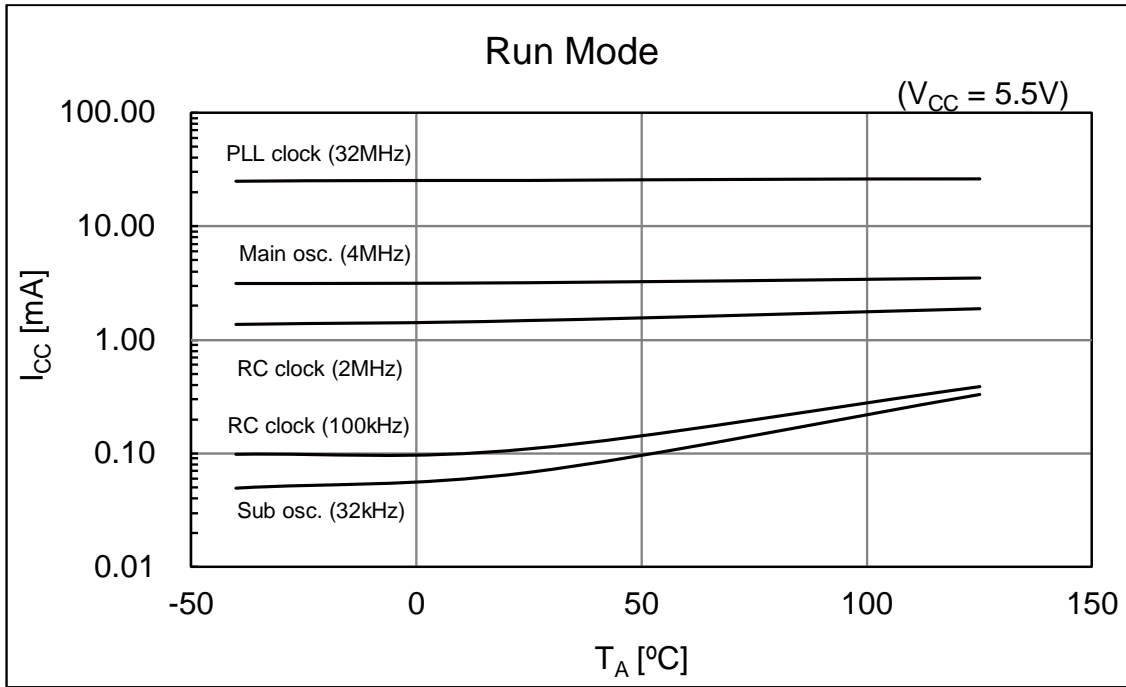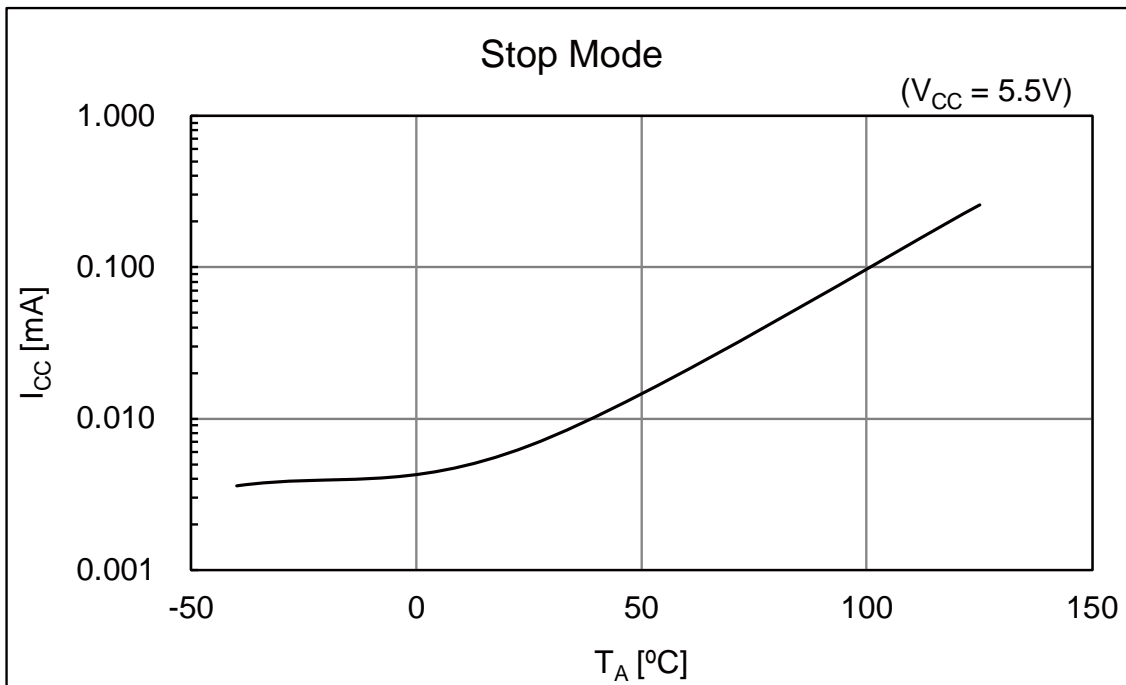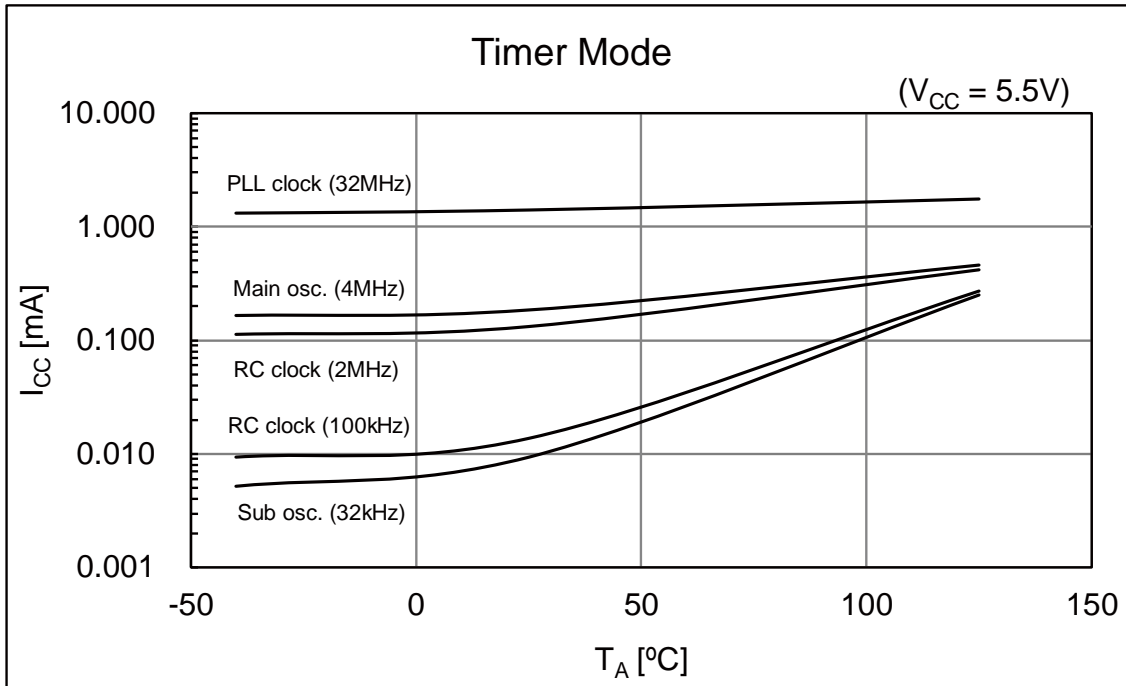
Used setting

Mode	Selected Source Clock	Clock/Regulator and FLASH Settings
Run mode	PLL	CLKS1 = CLKS2 = CLKB = CLKP1 = CLKP2 = 32MHz
	Main osc.	CLKS1 = CLKS2 = CLKB = CLKP1 = CLKP2 = 4MHz
	RC clock fast	CLKS1 = CLKS2 = CLKB = CLKP1 = CLKP2 = 2MHz
	RC clock slow	CLKS1 = CLKS2 = CLKB = CLKP1 = CLKP2 = 100kHz
	Sub osc.	CLKS1 = CLKS2 = CLKB = CLKP1 = CLKP2 = 32kHz
Sleep mode	PLL	CLKS1 = CLKS2 = CLKP1 = CLKP2 = 32MHz Regulator in High Power Mode, (CLKB is stopped in this mode)
	Main osc.	CLKS1 = CLKS2 = CLKP1 = CLKP2 = 4MHz Regulator in High Power Mode, (CLKB is stopped in this mode)
	RC clock fast	CLKS1 = CLKS2 = CLKP1 = CLKP2 = 2MHz Regulator in High Power Mode, (CLKB is stopped in this mode)
	RC clock slow	CLKS1 = CLKS2 = CLKP1 = CLKP2 = 100kHz Regulator in Low Power Mode, (CLKB is stopped in this mode)
	Sub osc.	CLKS1 = CLKS2 = CLKP1 = CLKP2 = 32kHz Regulator in Low Power Mode, (CLKB is stopped in this mode)
Timer mode	PLL	CLKMC = 4MHz, CLKPLL = 32MHz (System clocks are stopped in this mode) Regulator in High Power Mode, FLASH in Power-down / reset mode
	Main osc.	CLKMC = 4MHz (System clocks are stopped in this mode) Regulator in High Power Mode, FLASH in Power-down / reset mode
	RC clock fast	CLKMC = 2MHz (System clocks are stopped in this mode) Regulator in High Power Mode, FLASH in Power-down / reset mode
	RC clock slow	CLKMC = 100kHz (System clocks are stopped in this mode) Regulator in Low Power Mode, FLASH in Power-down / reset mode
	Sub osc.	CLKMC = 32 kHz (System clocks are stopped in this mode) Regulator in Low Power Mode, FLASH in Power-down / reset mode
Stop mode	stopped	(All clocks are stopped in this mode) Regulator in Low Power Mode, FLASH in Power-down / reset mode

15. Ordering Information

MCU with CAN Controller

Part Number	Flash Memory	Package*
CY96F6C5RBPMC-GS-UJE1	Flash A (160.5KB)	120-pin plastic LQFP (LQM120)
CY96F6C6RBPMC-GS-UJE1	Flash A (288.5KB)	120-pin plastic LQFP (LQM120)

*: For details about package, see "Package Dimension".

16. Package Dimension

TOP VIEW

BOTTOM VIEW

SIDE VIEW

DETAIL A

SECTION A -A'
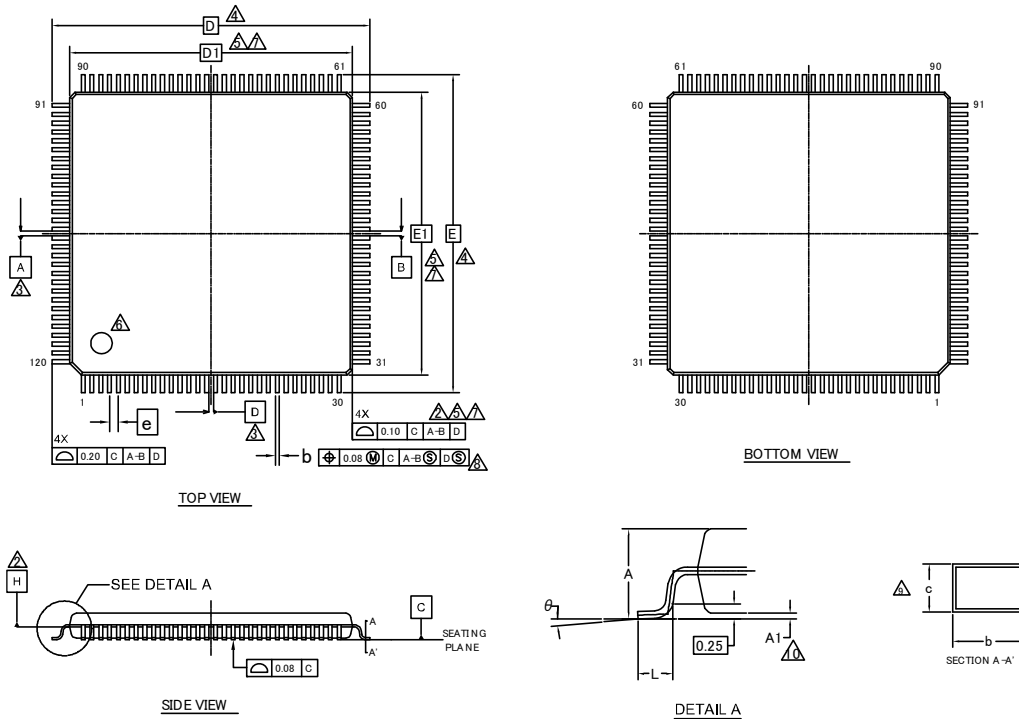
SYMBOL	DIMENSIONS		
	MIN.	NOM.	MAX.
A	—	—	1.70
A1	0.05	—	0.15
b	0.17	0.22	0.27
c	0.115	—	0.195
D	18.00 BSC		
D1	16.00 BSC		
e	0.50 BSC		
E	18.00 BSC		
E1	16.00 BSC		
L	0.45	0.60	0.75
θ	0°	—	8°

NOTES
1. ALL DIMENSIONS ARE IN MILLIMETERS.
2. DATUM PLANE H IS LOCATED AT THE BOTTOM OF THE MOLD PARTING LINE COINCIDENT WITH WHERE THE LEAD EXITS THE BODY.
3. DATUMS A-B AND D TO BE DETERMINED AT DATUM PLANE H.
4. TO BE DETERMINED AT SEATING PLANE C.
5. DIMENSIONS D1 AND E1 DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS 0.25mm PRE SIDE. DIMENSIONS D1 AND E1 INCLUDE MOLD MISMATCH AND ARE DETERMINED AT DATUM PLANE H.
6. DETAILS OF PIN 1 IDENTIFIER ARE OPTIONAL BUT MUST BE LOCATED WITHIN THE ZONE INDICATED.
7. REGARDLESS OF THE RELATIVE SIZE OF THE UPPER AND LOWER BODY SECTIONS. DIMENSIONS D1 AND E1 ARE DETERMINED AT THE LARGEST FEATURE OF THE BODY EXCLUSIVE OF MOLD FLASH AND GATE BURRS. BUT INCLUDING ANY MISMATCH BETWEEN THE UPPER AND LOWER SECTIONS OF THE MOLDER BODY.
8. DIMENSION b DOES NOT INCLUDE DAMBER PROTRUSION. THE DAMBAR PROTRUSION (S) SHALL NOT CAUSE THE LEAD WIDTH TO EXCEED b MAXIMUM BY MORE THAN 0.08mm. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE LEAD FOOT.
9. THESE DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.10mm AND 0.25mm FROM THE LEAD TIP.
10. A1 IS DEFINED AS THE DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT OF THE PACKAGE BODY.
11. JEDEC SPECIFICATION NO. REF: N/A.

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PACKAGE OUTLINE, 120 LEAD LQFP
18.0X18.0X1.7 MM LQM 120 REV**

17. Major Changes

Spansion Publication Number: MB966C0_DS704-00014-2v1-E

Page	Section	Change Results
Revision 1.0		
-	-	Initial release
Revision 2.0		
42	Electrical Characteristics DC Characteristics Current Rating	Changed the Value of "Power supply current in Timer modes" I_{CCTPLL} Typ: 2485µA → 1800µA (T_A = +25°C) Max: 2715µA → 2250µA (T_A = +25°C) Max: 4095µA → 3220µA (T_A = +105°C) Max: 5055µA → 4200µA (T_A = +125°C)
Revision 2.1		
-	-	Company name and layout design change
Rev.*B		
-	Marketing Part Numbers changed from an MB prefix to a CY prefix.	
5, 7, 68,69	1. Product Lineup 3. Pin Assignment 16. Ordering Information 17. Package Dimension	Package description modified to JEDEC description. FPT-120P-M21 → LQM120
68	16. Ordering Information	Revised Marketing Part Numbers as follows: Before) **MCU with CAN controller** MB96F6C5RBPMC-GSE1 MB96F6C5RBPMC-GSE2 MB96F6C6RBPMC-GSE1 MB96F6C6RBPMC-GSE2 **MCU without CAN controller** MB96F6C5ABPMC-GSE1 MB96F6C5ABPMC-GSE2 After) **MCU with CAN controller** CY96F6C5RBPMC-GS-UJE1 CY96F6C6RBPMC-GS-UJE1

NOTE: Please see "Document History" about later revised information.

Document History

Document Title: CY966C0 Series F2MC-16FX 16-bit Microcontroller
Document Number: 002-04723

Revision	ECN	Orig. of Change	Submission Date	Description of Change
**	–	KSUN	01/31/2014	Migrated to Cypress and assigned document number 002-4723. No change to document contents or format.
*A	5168020	KSUN	03/29/2016	Updated to Cypress template
*B	6003420	MIYH	12/25/2017	Revised the following items: Marketing Part Numbers changed from an MB prefix to a CY prefix. 1. Product Lineup 3. Pin Assignment 16. Ordering Information 17. Package Dimension For details, please see 18. Major Changes.

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